## LED Drivers for LCD Backlights

## 6ch boost LED driver which constant setting can be shared by I2C control

## BD9423EFV

### 1.1 General Description

BD9423EFV is a high efficiency driver for white LEDs and designed for large LCD panel. This IC is built-in high current drive and high responsibility type 6ch LED drivers and 1ch boost DCDC converter. BD9423EFV has some protect function against fault conditions, such as the over-voltage protection (OVP), LED OPEN and SHORT protection, the over current limit protection of DCDC (OCP). Therefore BD9423EFV is available for the fail-safe design over a wide range output voltage.
Moreover the functions and the detection voltage can be controlled by the I2C. This enables for the constant setting of external parts to be shared by I2C control, nevertheless the different usage condition.

## Features

■ Operating power supply voltage range:9.0V to 35.0 V

- Oscillator frequency: $\quad 200 \mathrm{kHz}(\mathrm{RT}=100 \mathrm{k} \Omega)$
- Operating Current:

9 mA (typ.)

- Operating temperature range: $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$


## Applications

- TV, Computer Display, Notebook, LCD Backlighting


## Key Specifications

- LED drivers Max curret
- Constant current accuracy

400mA per channel
$\pm 1.8 \%$ (IC only)

- Current analog (linear) dimming by ADIM pin
- Several protection functions

DCDC part
: OCP/OVP/UVLO
LED driver part :OPEN,SHORT detection

- SHORT detection voltage is set by LSP pin
- Error detection output by FAIL pin
- Master/Slave mode inside


### 1.2 Package

HTSSOP-B40:
Pin Pitch:
W(Typ) x D(Typ) x H(Max)
$13.60 \mathrm{~mm} \times 7.80 \mathrm{~mm} \times 1.00 \mathrm{~mm}$
0.65 mm

Figure 1. HTSSOP-B40

## Typical Application Circuit



Figure 2. Typical application circuit

### 1.3 Pin Configuration



Figure 3. Pin Configuration

### 1.4 Pin Descriptions

| No. | Name | Function | No. | Name | Function |
| :---: | :---: | :---: | :---: | :---: | :---: |
| 1 | VCC | Power supply pin | 40 | AGND | GND pin for analog part |
| 2 | FAIL | Abnormality detection output pin | 39 | UVLO | Low voltage malfunction detection pin |
| 3 | REG9V | 9.0 V regulator output pin | 38 | LSP | LED SHORT detection voltage setting pin |
| 4 | N.C. | - | 37 | LED_LV | LED feedback voltage setting pin |
| 5 | N | DC/DC switching output pin | 36 | ADIM_P | Pulse analog dimming signal input pin |
| 6 | PGND | Power GND pin | 35 | ADIM | Analog dimming DC voltage I/O pin |
| 7 | CS | DC/DC FET current detection pin | 34 | RT | Connecting pin for frequency setting resistor |
| 8 | OVP | OVP detection pin | 33 | FB | Error AMP output pin |
| 9 | FAIL_MODE | FAIL function selection pin | 32 | SS | Connecting pin for soft start |
| 10 | AGND | GND pin for analog part | 31 | CP | setting capacitor |
| 11 | LED1 | LED output 1 | 30 | S1 | Connecting pin for abnormality |
| 12 | LED2 | LED output 2 | 29 | S2 | detection setting capacitor |
| 13 | LED3 | LED output 3 | 28 | S3 | Connecting pin for LED1 constant current setting resistor |
| 14 | LED4 | LED output 4 | 27 | S4 | Connecting pin for LED2 constant current setting resistor |
| 15 | LED5 | LED output 5 | 26 | S5 | Connecting pin for LED3 constant current setting resistor |
| 16 | LED6 | LED output 6 | 25 | S6 | Connecting pin for LED4 constant current setting resistor |
| 17 | STB | ON/OFF pin | 24 | FAIL_RST | Connecting pin for LED5 constant current setting resistor |
| 18 | DVDD | Power supply pin for I2C part and register | 23 | SUMPWM | Connecting pin for LED6 constant current setting resistor |
| 19 | SDA | I2C data pin | 22 | DGND | FAIL output reset pin |
| 20 | SCL | I2C Clock pin | 21 | PWM | Master/Slave setting input/output pin |

### 1.5 Block Diagram



Figure 4. Block Diagram

1．6 Absolute maximum ratings $\left(\mathrm{Ta}=25^{\circ} \mathrm{C}\right)$

| Parameter | Symbol | Rating | Unit |
| :--- | :---: | :---: | :---: |
| Power supply voltage | VCC | $-0.3 \sim 36$ | V |
| Power dissipation | Pd | $4.7^{(\text {Note } 1)}$ | W |
| Junction temperature range | Tjmax | $-40 \sim+150$ | ${ }^{\circ} \mathrm{C}$ |
| Operation temperature range | Topr | $-40 \sim+85$ | ${ }^{\circ} \mathrm{C}$ |
| Storage temperature range | Tstg | $-55 \sim+150$ | ${ }^{\circ} \mathrm{C}$ |
| Maximum LED output current | ILED | $400^{\text {（Note2）（Note3）}}$ | mA |


| No． | Pin | Rating［V］ | No． | Pin | Rating［V］ |
| :---: | :---: | :---: | :---: | :---: | :---: |
| 1 | VCC | $-0.3 \sim 36$ | 40 | AGND | - |
| 2 | FAIL | $-0.3 \sim 36$ | 39 | UVLO | $-0.3 \sim 10.5$ |
| 3 | REG9V | $-0.3 \sim 13$ | 38 | LSP | $-0.3 \sim 7$ |
| 4 | N．C． | - | 37 | LED＿LV | $-0.3 \sim 7$ |
| 5 | N | $-0.3 \sim 13$ | 36 | ADIM＿P | $-0.3 \sim 20$ |
| 6 | PGND | - | 35 | ADIM | $-0.3 \sim 20$ |
| 7 | CS | $-0.3 \sim 7$ | 34 | RT | $-0.3 \sim 7$ |
| 8 | OVP | $-0.3 \sim 7$ | 33 | FB | $-0.3 \sim 7$ |
| 9 | FAIL＿MODE | $-0.3 \sim 7$ | 32 | SS | $-0.3 \sim 7$ |
| 10 | AGND | - | 31 | CP | $-0.3 \sim 7$ |
| 11 | LED1 | $-0.3 \sim 60$ | 30 | S1 | $-0.3 \sim 7$ |
| 12 | LED2 | $-0.3 \sim 60$ | 29 | S2 | $-0.3 \sim 7$ |
| 13 | LED3 | $-0.3 \sim 60$ | 28 | S3 | $-0.3 \sim 7$ |
| 14 | LED4 | $-0.3 \sim 60$ | 27 | S4 | $-0.3 \sim 7$ |
| 15 | LED5 | $-0.3 \sim 60$ | 26 | S5 | $-0.3 \sim 7$ |
| 16 | LED6 | $-0.3 \sim 60$ | 25 | S6 | $-0.3 \sim 7$ |
| 17 | STB | $-0.3 \sim 36$ | 24 | FAIL＿RST | $-0.3 \sim 22$ |
| 18 | DVDD | $-0.3 \sim 4.0$ | 23 | SUMPWM | $-0.3 \sim 7$ |
| 19 | SDA | $-0.3 \sim 4.0$ | 22 | DGND | - |
| 20 | SCL | $-0.3 \sim 4.0$ | 21 | PWM | $-0.3 \sim 22$ |

（Note1）In the case of mounting 4 layer glass epoxy base－plate of $70 \mathrm{~mm} \times 70 \mathrm{~mm} \times 1.6 \mathrm{~mm}, 37.6 \mathrm{~mW}$ is reduced at $1^{\circ} \mathrm{C}$ above $\mathrm{Ta}=25^{\circ} \mathrm{C}$ ．
（Note2）Wide VF variation of LED increases loss at the driver，which results in rise in package temperature．Therefore，the board needs to be designed with attention paid to heat radiation．
（Note3）This current value is per 1ch．It needs be used within a range not exceeding Pd．
Caution：Operating the IC over the absolute maximum ratings may damage the IC．The damage can either be a short circuit between pins or an open circuit between pins and the internal circuitry．Therefore，it is important to consider circuit protection measures，such as adding a fuse，in case the IC is operated over the absolute maximum ratings．

1．7 Thermal Resistance ${ }^{(\text {Note 1）}}$

| Parameter | $\underset{\mathrm{l}}{\text { Symbo }}$ | Thermal Resistance（Typ） |  | Unit |
| :---: | :---: | :---: | :---: | :---: |
|  |  | 1 層基板 ${ }^{\text {（Note 3）}}$ | 4 層基板 ${ }^{(N o t e ~ 4)}$ |  |
| HTSSOP－B40 |  |  |  |  |
| Junction to Ambient | $\theta_{\text {JA }}$ | 99.8 | 26.0 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| Junction to Top Characterization Parameter ${ }^{\text {（Note 2）}}$ | $\psi_{J T}$ | 5 | 2 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |

（Note 1）Based on JESD51－2A（Still－Air）
（Note 2）The thermal characterization parameter to report the difference between junction temperature and the temperature at the top center of the outside surface of the component package．
（Note 3）Using a PCB board based on JESD51－3．
（Note 4）Using a PCB board based on JESD51－5， 7.

1．8 Electrical Characteristics $1 / 3$（unless otherwise specified， $\mathrm{V}_{\mathrm{IN}}=\mathbf{2 4 V} \mathrm{Tj}=\mathbf{2 5 ^ { \circ }} \mathrm{C}$ ）

| Parameter | Symbol | Min | Typ | Max | Unit | Condition |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| 【Whole device】 |  |  |  |  |  |  |
| Operating circuit current | ICC | － | 9 | 16 | mA | STB＝3．0V，LED1－6＝ON，RT＝100k |
| Standby circuit current | ISTB | － | 15 | 25 | $\mu \mathrm{A}$ | STB＝0V |
| DVDD circuit current | IDVDD | － | 1.8 | － | mA | DVDD＝3．3V |
| 【UVLO block】 |  |  |  |  |  |  |
| VCC operating supply voltage | VUVLO＿VCC | 7.0 | 7.5 | 8.0 | V | VCC＝SWEEP UP |
| VCC hysteresis voltage | VUHYS＿VCC | 150 | 300 | 600 | mV | VCC＝SWEEP DOWN |
| UVLO release voltage | VUVLO＿UVLO | 2.40 | 2.50 | 2.60 | V | VUVLO＝SWEEP UP |
| UVLO HYS width | VUHYS＿UVLO | 100 | 200 | 400 | mV | VUVLO＝SWEP DOWN |
| UVLO pin input current | IUVLO | －2 | 0 | 2 | $\mu \mathrm{A}$ | VUVLO $=3.0 \mathrm{~V}$ |
| DVDD release voltage | VUVLO＿DVDD | 2.10 | 2.35 | 2.60 | V | VDVDD＝SWEEP UP |
| DVDD HYS width | VUHYS＿DVDD | 100 | 200 | 400 | mV | VDVDD＝SWEP DOWN |
| 【REG9V block】 |  |  |  |  |  |  |
| REG9V output voltage | REG9V | 8.91 | 9.0 | 9.09 | V | $\mathrm{IO}=0 \mathrm{~mA}, \mathrm{VCC}>11.0 \mathrm{~V}$ |
| REG9V max．output current | IREG9V | 20 | － | － | mA |  |
| 【DCDC block】 |  |  |  |  |  |  |
| Error AMP reference voltage | VEAMP | 0.97 | 1.00 | 1.03 | V | LED＿LV＝1．0V，LEDLV［3：0］＝0000 |
|  |  | 0.578 | 0.60 | 0.622 | V | LEDLV［3：0］＝1001 |
|  |  | 0.278 | 0.300 | 0.322 | V | LEDLV［3：0］＝1111 |
| FB sink current | IFBSINK | 85 | 100 | 115 | $\mu \mathrm{A}$ | LED＿LV＝1．0V，LEDx＝2．0V，VFB＝1．0V |
| FB source current（Master） | IFBSOURCEM | －115 | －100 | －85 | $\mu \mathrm{A}$ | $\begin{aligned} & \text { LED_LV=1.0V, LEDx=0.0V, } \\ & \text { VFB=1.0V,CS=0.0V } \end{aligned}$ |
| FB source current（Slave） | IFBSWRCKS | －230 | －200 | －170 | $\mu \mathrm{A}$ | LEDx $=0 \mathrm{~V}, \mathrm{VFB}=1.0 \mathrm{~V}, \mathrm{CS}=5.0 \mathrm{~V}$ |
| LED＿LV pin input current | ILED＿LV | －2 | 0 | 2 | $\mu \mathrm{A}$ | VLED＿LV＝3．0V |
| Oscillation frequency | FCT | 190 | 200 | 210 | kHz | $\mathrm{RT}=100 \mathrm{k} \Omega$ ，FOSC［4：0］＝00000 |
| MAX DUTY | DMAX | 83 | 89 | 96 | \％ |  |
| SS pin source current | ISS | －3．75 | －3．0 | －2．25 | $\mu \mathrm{A}$ | SS $=0 \mathrm{~V}$ |
| SS pin release voltage | VSS | 3.8 | 4.0 | 4.2 | V | SS＝SWEEP UP |
| N pin source resistor | RONH | － | 2.5 | 3.5 | $\Omega$ | ION＝－10mA |
| $N$ pin sink resistor | RONL | － | 3.0 | 4.2 | $\Omega$ | $1 \mathrm{ON}=10 \mathrm{~mA}$ |

1．8 Electrical Characteristics $2 / 3$（unless otherwise specified， $\mathrm{V}_{1 \mathrm{~N}}=\mathbf{2 4 V} \mathrm{Tj}_{\mathrm{j}}=\mathbf{2 5 ^ { \circ }} \mathrm{C}$ ）

| Parameter | Symbol | Min | Typ | Max | Unit | Condition |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| 【DCDC protection block】 |  |  |  |  |  |  |
| OCP detection voltage | VOCP | 0.405 | 0.45 | 0.495 | V | VCS＝SWEEP UP |
| OVP detection voltage | VOVP | 2.91 | 3.00 | 3.09 | V | VOVP＝SWEEP UP， OVPSET［3：0］＝0000 |
| OVP hysteresis voltage | VOVPHYS | 10 | 50 | 100 | mV | VOVP＝SWEEP DOWN， OVPSET［3：0］＝0000 |
| OVP pin input current | IOVP | －2 | 0 | 2 | $\mu \mathrm{A}$ | VOVP＝3．0V |
| SCP detection voltage | VSCP | 0.12 | 0.20 | 0.28 | V | VOVP＝SWEEP DOWN |
| 【LED driver block】 |  |  |  |  |  |  |
| S pin voltage 1 | VSLED1 | 196 | 200 | 204 | mV | ADIM＝1．0V，ADIMGAIN［3：0］＝0000 |
|  |  | 294.6 | 300 | 305.4 | mV | ADIM $=1.5 \mathrm{~V}$ ，ADIMGAIN［3：0］＝0000 |
|  |  | 392.8 | 400 | 407.2 | mV | ADIM $=2.0 \mathrm{~V}$, ADIMGAIN［3：0］＝0000 |
|  |  | 491 | 500 | 509 | mV | ADIM $=2.5 \mathrm{~V}$, ADIMGAIN［3：0］＝0000 |
| S pin voltage 2 | VSLED2 | 101.7 | 106 | 110.3 | mV | ADIM＝1．0V，ADIMGAIN［3：0］＝1111 |
|  |  | 153.2 | 159 | 164.8 | mV | ADIM $=1.5 \mathrm{~V}$, ADIMGAIN［3：0］＝1111 |
|  |  | 204.3 | 212 | 219.7 | mV | ADIM $=2.0 \mathrm{~V}$ ，ADIMGAIN［3：0］＝1111 |
|  |  | 254.4 | 265 | 275.6 | mV | ADIM＝2．5V，ADIMGAIN［3：0］＝1111 |
| LED current rise time | ILEDtr | － | 400 | 760 | ns | ADIM $=0.3 \mathrm{~V}, \mathrm{RS}=2 \Omega$ ， $\mathrm{DVDD}=0 \mathrm{~V}$ |
| LED current fall time | ILEDtf | － | 100 | 280 | ns | $\mathrm{ADIM}=0.3 \mathrm{~V}, \mathrm{RS}=2 \Omega$ ， $\mathrm{DVDD}=0 \mathrm{~V}$ |
| OPEN detection voltage | VOPEN | 0.12 | 0.20 | 0.28 | V | VLED＝SWEEP DOWN |
| SHORT detection voltage | VSHORT | 5.7 | 6.0 | 6.3 | V | VLED＝SWEEPUP，VLSP＝1．2V， LSPSET［3：0］＝0000 |
| SHORT MASK voltage | VSHTMASK | 2.85 | 3.0 | 3.15 | V |  |
| LSP pin input current | ILSP | －2 | 0 | 2 | $\mu \mathrm{A}$ | VLSP＝3．0V |
| 【Analog dimming block】 |  |  |  |  |  |  |
| ADIM＿P pin HIGH voltage | ADIM＿PH | 2.0 | － | 5.5 | V |  |
| ADIM＿P pin LOW voltage | ADIM＿PL | －0．3 | － | 0.8 | V |  |
| ADIM＿P Pin input MASK voltage | ADIM＿PPU | 6.5 | － | 18 | V |  |
| ADIM＿P pin pull－down R | RADIM＿P | 2.4 | 4.0 | 5.6 | $\mathrm{M} \Omega$ | VADIM＿P＝3．0V |
| ADIM pin output voltage H （During output） | ADIMH | 2.462 | 2.500 | 2.538 | V | VADIM＿P＝3．3V |
| ADIM pin output voltage L （During output） | ADIML | － | 0.0 | 0.05 | V | VADIM＿P＝0．0V |
| ADIM pin output R （During output） | ADIMR | 6.6 | 10 | 15 | k $\Omega$ | VADIM＿P＝0．0V |
| ADIM pin input current （During input） | IADIM | －2 | 0 | 2 | $\mu \mathrm{A}$ | VADIM＿P＝9．0V，VADIM $=2.5 \mathrm{~V}$ |

1．8 Electrical Characteristics $\mathbf{3 / 3}$（unless otherwise specified， $\mathrm{V}_{\mathrm{IN}}=\mathbf{2 4 V} \mathbf{T j}=\mathbf{2 5}{ }^{\circ} \mathrm{C}$ ）

| Parameter | Symbol | Min | Typ | Max | Unit | Condition |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| 【STB block】 |  |  |  |  |  |  |
| STB pin HIGH voltage | VSTBH | 2.0 | － | 18 | V |  |
| STB pin LOW voltage | VSTBL | －0．3 | － | 0.8 | V |  |
| STB pin pull－down Resistor | RSTB | 0.6 | 1.0 | 1.4 | $\mathrm{M} \Omega$ | STB＝3．0V |
| 【PWM block】 |  |  |  |  |  |  |
| PWM pin HIGH voltage | VPWMH | 1.5 | － | 20 | V |  |
| PWM pin LOW voltage | VPWML | －0．3 | － | 0.8 | V |  |
| PWM pin pull－down Resistor | RPWM | 180 | 300 | 420 | k $\Omega$ | PWM $=3.0 \mathrm{~V}$ |
| 【Abnormality detection block】 |  |  |  |  |  |  |
| FAIL pin LOW output voltage | VFAILL | 0.0 | 0.15 | 0.3 | V | $\mathrm{IOL}=500 \mu \mathrm{~A}$ |
| FAIL＿RST pin Input HIGH voltage | VFAIL＿INH | 2.0 | － | 20 | V |  |
| FAIL＿MODE pin Input HIGH voltage | VFAIL＿INH | 2.0 | － | 5.5 | V |  |
| FAIL＿MODE，FAIL＿RST pin Input LOW voltage | VFAIL＿INL | －0．3 | － | 0.8 | V |  |
| FAIL＿MODE，FAIL＿RST pin Input pull－down Resistor | RFAIL | 60 | 100 | 140 | k $\Omega$ | $\mathrm{VIN}=3.0 \mathrm{~V}$ |
| CP detection voltage | VCP | 2.91 | 3.0 | 3.09 | V | CP＝SWEEP UP |
| CP source current | ICP | －3．3 | －3．0 | －2．7 | $\mu \mathrm{A}$ | $\mathrm{CP}=0 \mathrm{~V}$ |
| 【I2C block】 |  |  |  |  |  |  |
| SCL，SDA input HIGH voltage | VI2C＿INH | $0.8{ }^{*} \mathrm{DVDD}$ | － | 3.6 | V |  |
| SCL，SDA input LOW voltage | VI2C＿INL | －0．3 | － | $0.2 *$ VVD | V |  |
| SCL，SDA input HIGH current | II2C＿INH | － | － | 10 | $\mu \mathrm{A}$ | DVDD $=3.3 \mathrm{~V}, \mathrm{VIN}=3.3 \mathrm{~V}$ |
| SCL，SDA input LOW current | II2C＿INL | －10 | － | － | $\mu \mathrm{A}$ | DVDD $=3.3 \mathrm{~V}, \mathrm{VIN}=0 \mathrm{~V}$ |
| L level SDA output | VSDA＿OL | － | － | 0.4 | V |  |
| 【Master／Slave selection block】 |  |  |  |  |  |  |
| SUMPWM pin input HIGH voltage | VSUM＿INH | 2.0 | － | 5.5 | V |  |
| SUMPWM pin input LOW voltage | VSUM＿INL | －0．3 | － | 0.8 | V |  |
| SUMPWM pin pull－down Resistor | RSUM | 60 | 100 | 140 | k $\Omega$ | $\mathrm{VIN}=3.0 \mathrm{~V}$ |

### 1.9 Typical Performance Curves

(reference data)


Figure 5. Operating circuit current


Figure 7. Duty Cycle vs FB character


Figure 6. Standby circuit current


Figure 8. Sx vs ADIM character
1.10 Operating range

| Parameter | Symbol | Range | Unit |
| :--- | :---: | :---: | :---: |
| VCC power supply voltage | VCC | 9 to 35 | V |
| DVDD power supply voltage | VDD | 2.7 to 3.6 | V |
| Boost-up oscillation frequency | FCT | 50 to $1250^{(\text {Note1) }}$ | kHz |
| ADIM input voltage | VADIM | 0.2 to 2.5 | V |
| ADIM_P input frequency | FADIM_P | to 20 k | Hz |
| LSP pin input voltage | VLSP | 0.8 to 3 | V |
| LED_LV pin input voltage | VLED_LV | 0.3 to 1.8 | V |
| FB pin output voltage | VFB | 0 to 5.0 | V |
| PWM pin input frequency (With DVDD) | FPWM | 0,100 to 25 k | Hz |
| PWM pin input Low width (With DVDD) | TLPWM | from 157 ns | ns |
| SCL Clock frequency | FSCL | to 400 | kHz |

(Note1) When driving the external FET with high frequency, it may increase FET heat generation, therefore please do the setting carefully.
1.11 Recommendation range of external parts

| Parameter | Symbol | Range | Unit |
| :--- | :---: | :---: | :---: |
| VCC pin connection capacitance | CVCC | 1.0 to 10 | $\mu \mathrm{~F}$ |
| DVDD pin connection capacitance | CDVDD | 0.047 to 1.0 | $\mu \mathrm{~F}$ |
| Soft start setting capacitance | CSS | 0.001 to 1.0 | $\mu \mathrm{~F}$ |
| Timer latch setting capacitance | CCP | 0.001 to 2.7 | $\mu \mathrm{~F}$ |
| Boost-up frequency setting resistor | RRT | 12 to $150^{\text {(Note2) }}$ | $\mathrm{k} \Omega$ |
| REG9V pin connection capacitance | CREG9V | 1.0 to 10 | $\mu \mathrm{~F}$ |

(Note2) It depends on FOSC[4:0] register value, but please do the setting that make the oscillation frequency within the specification written in section 1.10 . The operating condition described above is for single IC constants. Adequate attention must be paid when setting the constants at actual set.

### 1.12 I2C command interface

### 1.12.1 Overview and condition

BD9423EF are using host CPU and Command Interface by I2C bus system. BD9423EFV register setting from 00h to 08h range is possible not only Write but also can Read. Besides, other than slave address, this IC also can perform to design 1bit Select Address and then do the Write and Read.
I2C bus slave mode format is shown as below.


S: Start Condition
Slave Address: After the set Slave Address (7bit) by ADDR, there is one more bit of Read Mode (H") or Write Mode (L") and the data will be sent in total of 8bit. (MSB format) BD9423EFV slave address is 46 h .
A: The acknowledge send and receive data is added by Acknowledge Bit as byte per byte.
When the send and receive data is correctly done, " $L$ " will be sent and received.
When it is " H ", acknowledge will be gone.
Select Address: BD9423EFV will use 1 byte of select address. (MSB format)
Data: Data Byte, send and receive data. (MSB format)
P: Stop Condition


Figure 9. Command Interface


Figure 10. Repeated Start Condition
1.12.2 Data format

1byte Write format


Figure 11. 1byte Write Data Format
1byte Read format (Read from select address=00h)


Figure 12. 1 byte Read Data Format (Select Address=00h)
1byte Read format (Read from specific Select Address)


Figure 13. 1byte Read Data Format (specified select address)
Consecutive Write format


Figure 14. Consecutive Write Data Format
Consecutive Read format (Read from specific Select Address)


Figure 15. Consecutive Read Data Format

### 1.12.3 Signal control specification

Bus Line and I/O stage electrical specification and timing


Figure 16. Timing chart

Table 1. SDA and SCL Bus Line characteristic (Unless otherwise stated $\mathrm{Ta}=25^{\circ} \mathrm{C}, \mathrm{DVDD}=3.0 \mathrm{~V}$ )

| Parameter |  | Symbol | High speed mode |  | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Min. | Max. |  |
| 1 | SCL clock frequency |  | fSCL | 0 | 400 | kHz |
| 2 | Bus Free Time between "Stop" Condition and "Start" Condition. | tBUF | 1.3 | - | $\mu \mathrm{s}$ |
| 3 | Hold Time (Resend) "Start" Condition. After this period, the first Clock Pulse will be generated. | tHDSTA | 0.6 | - | $\mu \mathrm{s}$ |
| 4 | SCL clock LOW state Hold Time | tLOW | 1.3 | - | $\mu \mathrm{s}$ |
| 5 | SCL clock HIGH state Hold Time | tHIGH | 0.6 | - | $\mu \mathrm{s}$ |
| 6 | Resend "Start" Condition set-up time | tSUSTA | 0.6 | - | $\mu \mathrm{s}$ |
| 7 | Data Hold Time | tHDDAT | $0^{\text {(Note 1) }}$ | - | $\mu \mathrm{s}$ |
| 8 | Data Set-up Time | tSUDAT | 100 | - | ns |
| 9 | SDA and SCL signal rising time | tR | $20+0.1 \mathrm{Cb}$ | 300 | ns |
| 10 | SDA and SCL signal falling time | tF | $20+0.1 \mathrm{Cb}$ | 300 | ns |
| 11 | "Stop" Condition set-up time | tSUSTO | 0.6 | - | $\mu \mathrm{s}$ |
| 12 | Each Bus Line capacitive load | Cb | - | 400 | pF |

Above values are all $\mathrm{V}_{\mathrm{IH} \text { min }}$ and $\mathrm{V}_{\mathrm{IL} \text { max }}$ level supported.
(Note1) Please note that the master device has uncertain interval maximum 300 ns for the negative edge of SLC, therefore SDA is necessary at least 300 ns hold time.

### 1.13 Register map and description

Slave address (Device address) for BD9423EFV is 46h. Please refer to section 1.12 I 2 C command interface for I2C details.
Update timing for each register is as follows.
(1) Data will reflect immediately after register is written.
(2) Data will reflect at next PWM rise after register is written (Refer to Section 1.14 PWM Phase shift setting)
(3) Data will reflect as PWM=Low after register is written.

Sequence that is assumed for each register will be as follow. (Please refer to 3.8 .1 start up and shut down sequences). Writing is possible at any timing, however it is classified by the consideration of register function.
(A) Initial command: Please input the command before input the STB pin. It is assumed to set a condition for the application.
(B) Dimming command: It is possible to input the command before or after STB pin.

| Address | R/W | ${ }_{\substack{\text { litial } \\ \text { value }}}^{\text {net }}$ | Register name | Bit7 | Bit6 | Bit5 | Bit4 | Bit3 | Bit2 | Bit1 | Bit0 |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| 00h | R/W | 00h | SOFTRST | - | - | - | - | - |  | FAILSORST | PHASERST |
|  |  |  | Update timing | - | - | - | - | - | - | (1) | (1) |
|  |  |  | Write sequence | - | - | - | - | - | - | (B) | (B) |
| 01h | R/W | 00h | LEDDIS | - | - | LED6DIS | LED5DIS | LED4DIS | LED3DIS | LED2DIS | LED1DIS |
|  |  |  | Update timing | - | - | (3) | (3) | (3) | (3) | (3) | (3) |
|  |  |  | Write sequence | - | - | (A) | (A) | (A) | (A) | (A) | (A) |
| 02h | R/W | 00h | LEDPHASE | FOSC4 | FOSC3 | FOSC2 | FOSC1 | FOSC0 | LEDPHASE2 | LEDPHASE1 | LEDPHASEO |
|  |  |  | Update timing | (1) | (1) | (1) | (1) | (1) | (2) | (2) | (2) |
|  |  |  | Write sequence | (A) | (A) | (A) | (A) | (A) | (A) | (A) | (A) |
| 03h | R/W | 00h | ADIMGAIN | CPADJ1 | CPADJO | SSADJ1 | SSADJO | $\begin{aligned} & \text { ADIM } \\ & \text { GAIN3 } \end{aligned}$ | $\begin{aligned} & \hline \text { ADIM } \\ & \text { GAIN2 } \end{aligned}$ | $\begin{aligned} & \hline \text { ADIM } \\ & \text { GAIN1 } \end{aligned}$ | $\begin{aligned} & \text { ADIM } \\ & \text { GAINO } \end{aligned}$ |
|  |  |  | Update timing | (1) | (1) | (1) | (1) | (1) | (1) | (1) | (1) |
|  |  |  | Write sequence | (A) | (A) | (A) | (A) | (A) | (A) | (A) | (A) |
| 04h | R/W | 00h | OVPSET | OVPSET3 | OVPSET2 | OVPSET1 | OVPSETO | LSPSET3 | LSPSET2 | LSPSET1 | LSPSETO |
|  |  |  | Update timing | (1) | (1) | (1) | (1) | (1) | (1) | (1) | (1) |
|  |  |  | Write sequence | (A) | (A) | (A) | (A) | (A) | (A) | (A) | (A) |
| 05h | R/W | 00h | SFTONOFF | - | - | MSTSLVSFT | MSTSLVSEL | SFTONT1 | SFTONTO | SFTOFFT1 | SFTOFFTO |
|  |  |  | Update timing | - | - | (1) | (1) | (1) | (1) | (1) | (1) |
|  |  |  | Write sequence | - |  | (A) | (A) | (B) | (B) | (B) | (B) |
| 06h | R/W | 00h | LOPMSK | SCPMSK | OVPMSK | LOPMSK6 | LOPMSK5 | LOPMSK4 | LOPMSK3 | LOPMSK2 | LOPMSK1 |
|  |  |  | Update timing | (1) | (1) | (1) | (1) | (1) | (1) | (1) | (1) |
|  |  |  | Write sequence | (B) | (B) | (B) | (B) | (B) | (B) | (B) | (B) |
| 07h | R/W | 00h | LSPMSK | - | - | LSPMSK6 | LSPMSK5 | LSPMSK4 | LSPMSK3 | LSPMSK2 | LSPMSK1 |
|  |  |  | Update timing | - | - | (1) | (1) | (1) | (1) | (1) | (1) |
|  |  |  | Write sequence | - | - | (B) | (B) | (B) | (B) | (B) | (B) |
| 08h | R/W | 00h | LEDLVSET | - | - | IFBSET1 | IFBSETO | Ledlvset3 | LEDLVSET2 | LEDLVSET1 | Ledlvseto |
|  |  |  | Update timing | - | - | (1) | (1) | (1) | (1) | (1) | (1) |
|  |  |  | Write sequence | - | - | (A) | (A) | (A) | (A) | (A) | (A) |

Note) "-": Invalid during Write, "0" during Read
Please do not write register other than 00h-08h. Besides, Read value from register other than 00h-08h is disabled.

## -ADDR=00h

> SOFTRST (SoftRESET control register: Read/Write)

| Bit | 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Register <br> Name | - | - | - | - | - |  | FAILSO |  |
| Initial Value | - | - | - | - | - | - | 0 | 0 |


| FAILSORST | RESET setting |
| :---: | :---: |
| 0 | Normal |
| 1 | Latch OFF release, Protection operation mask |

When FAILSORST is set as 1 (FAILSORST=1), protection circuit and FAIL are reset.
It is same with the operation when FAIL_RST pin=High.
During FAILSORST=1, latch OFF protection operation is masked.

| PHASERST | RESET setting |
| :---: | :---: |
| 0 | Normal |
| 1 | Counter clear |

When PHASERST=1, logics other than Phase shift part register are reset. Register values shown in the section 1.13 will not be reset. In order to release reset, please write PHASERST=0, it will return to normal condition.

## -ADDR=01h

LEDDIS (LED driver disable setting register: Read/Write)

| Bit | 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Register <br> name | - | - | LED6DIS | LED5DIS | LED4DIS | LED3DIS | LED2DIS | LED1DIS |
| Initial Value | - | - | 0 | 0 | 0 | 0 | 0 | 0 |


| LEDDIS | Disable Control |
| :---: | :---: |
| 0 | Enable (LED driver operates when PWM=H) |
| 1 | Disable (LED driver is not used) |

Unused channel will be set. The unused channel will not detect the abnormality (Short, Open).

## -ADDR=02h

LEDPHASE (Phase shift setting, FCT setting register: Read/Write)

| Bit | 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Register <br> name | FOSC4 | FOSC3 | FOSC2 | FOSC1 | FOSC0 | LEDPHASE2 | LEDPHASE1 | LEDPHASE0 |
| Initial Value | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 |


| FOSC[4:0] | FOSC setting | FCT default=200kHz |
| :---: | :---: | :---: |
| 00000 | 1.000 time | 200 kHz |
| 00001 | 0.250 time | 50 kHz |
| 00010 | 0.375 time | 75 kHz |
| 00011 | 0.500 time | 100 kHz |
| 00100 | 0.625 time | 125 kHz |
| 00101 | 0.750 time | 150 kHz |
| 00110 | 0.875 time | 175 kHz |
| 00111 | 1.000 time | 200 kHz |
| 01000 | 1.125 times | 225 kHz |
| 01001 | 1.250 times | 250 kHz |
| 01010 | 1.375 times | 275 kHz |
| 01011 | 1.500 times | 300 kHz |
| 01100 | 1.625 times | 325 kHz |
| 01101 | 1.750 times | 350 kHz |
| 01110 | 1.875 times | 375 kHz |
| 01111 | 2.000 times | 400 kHz |
| 10000 | 2.125 times | 425 kHz |
| 10001 | 2.250 times | 450 kHz |
| 10010 | 2.375 times | 475 kHz |
| 10011 | 2.500 times | 500 kHz |
| 10100 | 2.625 times | 525 kHz |
| 10101 | 2.750 times | 550 kHz |
| 10110 | 2.875 times | 575 kHz |
| 10111 | 3.000 times | 600 kHz |
| 11000 | 3.125 times | 625 kHz |
| 11001 | 3.250 times | 650 kHz |
| 11010 | 3.375 times | 675 kHz |
| 11011 | 3.500 times | 700 kHz |
| 11100 | 3.625 times | 725 kHz |
| 11101 | 3.750 times | 750 kHz |
| 11110 | 3.875 times | 775 kHz |
| 11111 | 4.000 times | 800 kHz |

Oscillating frequency FCT will be set.
When $\mathrm{RT}=100 \mathrm{k} \Omega$, default frequency is 200 kHz , frequency will be set as the values shown in above table.
Register is setting based on how many times of frequency base, therefore, please always connect a resistor at RT terminal.

| LEDPHASE[2:0] | LEDPHASE control |
| :---: | :---: |
| 000 | Phase1 setting (0 shift) |
| 001 | Phase2 setting (1/2T shift) |
| 010 | Phase3 setting (1/3T shift) |
| 011 | Phase4 setting (1/4T shift) |
| 100 | Phase5 setting (1/5T shift) |
| 101 | Phase6 setting (1/6T shift) |
| 110 |  |
| 111 |  |

Phase shift setting will be done. Please refer to section 1.14 "PWM phase shift setting" for each phase shift timing.
-ADDR=03h
ADIMGAIN (ADIM GAIN Setting, CP and SS time setting register: Read/Write)

| Bit | 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Register <br> name | CPADJ1 | CPADJ0 | SSADJ1 | SSADJ0 | ADIMGAIN3 | ADIMGAIN2 | ADIMGAIN1 | ADIMGAIN0 |
| Initial value | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 |


| CPADJ[1:0] | CP time setting |
| :---: | :---: |
| 00 | 1 time |
| 01 | 2 times |
| 10 | $1 / 2$ time |
| 11 | $1 / 4$ time |

CP timer time, Tcp can be set.
CP timer time can be decided by, $\mathrm{Tcp}[\mathrm{s}]=(\mathrm{Ccp}[\mathrm{F}] \times 3 \mathrm{~V} \times \mathrm{CPADJ}) / 3 \mu \mathrm{~A}$.

| SSADJ[1:0] | SS time setting |
| :---: | :---: |
| 00 | 1 time |
| 01 | 2 times |
| 10 | $1 / 2$ time |
| 11 | $1 / 4$ time |

SS release time, Tss can be set.
SS release time can be decided by, Tss[s] = (Css[F] $\times 4 \mathrm{~V} \times$ SSADJ $) / 3 \mu \mathrm{~A}$.

| ADIMGAIN[3:0] | ADIMGAIN setting |
| :---: | :---: |
| 0000 | 0.200 time |
| 0001 | 0.194 time |
| 0010 | 0.188 time |
| 0011 | 0.181 time |
| 0100 | 0.175 time |
| 0101 | 0.169 time |
| 0110 | 0.163 time |
| 0111 | 0.156 time |
| 1000 | 0.150 time |
| 1001 | 0.144 time |
| 1010 | 0.138 time |
| 1011 | 0.131 time |
| 1100 | 0.125 time |
| 1101 | 0.119 time |
| 1110 | 0.113 time |
| 1111 | 0.106 time |

ADIM gain will be set. ADIM pin voltage $\times$ ADIMGAIN $=S \times$ pin voltage.
-ADDR=04h
OVPSET (OVP voltage, LSP voltage setting register: Read/Write)

| Bit | 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Register <br> name | OVPSET3 | OVPSET2 | OVPSET1 | OVPSET0 | LSPSET3 | LSPSET2 | LSPSET1 | LSPSET0 |
| Initial value | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 |


| OVPSET[3:0] | OVP voltage setting | OVP default=90V |
| :---: | :---: | :---: |
| 0000 | 3.00 V | 90 V |
| 0001 | 0.90 V | 27 V |
| 0010 | 1.05 V | 32 V |
| 0011 | 1.20 V | 36 V |
| 0100 | 1.35 V | 41 V |
| 0101 | 1.50 V | 45 V |
| 0110 | 1.65 V | 50 V |
| 0111 | 1.80 V | 54 V |
| 1000 | 1.95 V | 59 V |
| 1001 | 2.10 V | 63 V |
| 1010 | 2.25 V | 68 V |
| 1011 | 2.40 V | 72 V |
| 1100 | 2.55 V | 77 V |
| 1101 | 2.70 V | 81 V |
| 1110 | 2.85 V | 86 V |
| 1111 | 3.00 V | 90 V |

OVP voltage will be set. When setting the OVP detection resistor 30 times (OVP upper side resistor : OVP lower side resistor=29:1), the setting shown in above table can be done.

| LSPSET[3:0] | LSP voltage setting | LSP detection voltage value |
| :---: | :---: | :---: |
| 0000 | LSP pin input | 4 V to 15 V |
| 0001 | 0.8 V | 4 V |
| 0010 | 0.8 V | 4 V |
| 0011 | 0.8 V | 4 V |
| 0100 | 0.8 V | 4 V |
| 0101 | 1.0 V | 5 V |
| 0110 | 1.2 V | 6 V |
| 0111 | 1.4 V | 7 V |
| 1000 | 1.6 V | 8 V |
| 1001 | 1.8 V | 9 V |
| 1010 | 2.0 V | 10 V |
| 1011 | 2.2 V | 11 V |
| 1100 | 2.4 V | 12 V |
| 1101 | 2.6 V | 13 V |
| 1110 | 2.8 V | 14 V |
| 1111 | 3.0 V | 15 V |

LSP voltage will be set. When LSPSET[3:0]=0000, LSP pin voltage will be used as LSP detection reference voltage.
Other than LSPSET[3:0]=0000, IC internal reference voltage will be used, therefore external bias setting can be removed.
If you set the LSP by this register, it will be the priority rather than LSP pin voltage.
-ADDR=05h

| SFTONOFF (SOFT ON, SOFT OFF setting register, Master/Slave setting register: Read/Write) |
| :--- |
| Bit 7 6 5 4 3 2 1 <br> Register  - MSTSLV MSTSLV    <br> Name - - SFT SEL SFTONT1 SFTONT0 SFTOFFT1 SFTOFFT0 |
| Initial Value |


| MSTSLVSFT | Master/Slave software setting |
| :---: | :---: |
| 0 | Master mode |
| 1 | Slave mode |

(Note) Valid when MSTSLVSEL =1

| MSTSLVSEL | Master/Slave selection setting |
| :---: | :---: |
| 0 | Hardware recognition (CSDET output detection) |
| 1 | MSTSLVSEL register control |

Master/Slave setting is possible when MSTSLVSEL=1. This setting means for when CS pin is set to open. Please separately connect the SUMPWM pin between the IC.

| SFTONT[1:0] | Soft ON time setting |
| :---: | :---: |
| 00 | Soft ON function stop |
| 01 | 2time |
| 10 | 1time (correspond to fsw 10CLK) |
| 11 | 1/2time |

Set Soft ON time when PWM $=\mathrm{L} \rightarrow \mathrm{H}$. CLK when N pin is operating in MAX duty.

| SFTOFFT[1:0] | Soft OFF time setting |
| :---: | :---: |
|  | 1 time (correspond to fsw 15CLK) <br> 00 |
| However, when Soft ON is $1 / 2$ time (SFTONT[1:0]=11), it will become 1/2time. |  |
| 01 | 2times <br> However, when Soft ON is 1 time (SFTONT[1:0]=10), it will become 1time, <br> when Soft On is $1 / 2$ time (SFTONT[1:0]=11), it will become 1/2time. |
| 10 | $1 / 2$ time |
| 11 | - |

Set Soft OFF time when PWM $=H \rightarrow$. CLK when $N$ pin is operating in MAX duty.

## -ADDR=06h

LOPMSK (SCP, OVP, LOP Mask register: Read/Write)

| Bit | 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Register <br> Name | SCPMSK | OVPMSK | LOPMSK6 | LOPMSK5 | LOPMSK4 | LOPMSK3 | LOPMSK2 | LOPMSK1 |
| Initial Value | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 |


| SCPMSK | Short circuit protection (SCP) Mask control |
| :---: | :---: |
| 0 | Normal |
| 1 | SCP Mask |


| OVPMSK | Over voltage protection (OVP) Mask control |
| :---: | :---: |
| 0 | Normal |
| 1 | OVP Mask |

Mask the SCP and OVP detection.

| LOPMSK | LED Open protection (LOP) Mask control |
| :---: | :---: |
| 0 | Normal |
| 1 | LOP Mask |

Mask LED open detection for each channel.
Example 1: When masking the OVP, ADDR=06h, DATA=40h
Example 2: When masking the SCP and OVP, ADR=06h and DATA=C0h
Example 3: When masking the LED1 LOP, ADDR=06h, DATA=01h

- ADDR=07h

LSPMSK (LSP Mask register: Read/Write)

| Bit | 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Register <br> Name | - | - | LSPMSK6 | LSPMSK5 | LSPMSK4 | LSPMSK3 | LSPMSK2 | LSPMSK1 |
| Initial Value | - | - | 0 | 0 | 0 | 0 | 0 | 0 |


| LSPMSK | LED Short protection (LSP) Mask control |
| :---: | :---: |
| 0 | Normal |
| 1 | LSP Mask |

Example 1: When masking the LED6 LSP, ADDR=07h, DATA=20h

## -ADDR=08h

LEDLVSET (LED_LV voltage, FB current setting register: Read/Write)

| Bit | 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Register | - | - | IFBSET1 | IFBSET0 | LEDLVSET3 | LEDLVSET2 | LEDLVSET1 | LEDLVSET0 |
| Name | - | - | 0 | 0 | 0 | 0 | 0 | 0 |
| Initial Value | - | - | 0 | 0 |  |  |  |  |


| IFBSET[1:0] | FB current setting |
| :---: | :---: |
| 00 | 1 time |
| 01 | 2times |
| 10 | 1/2time |
| 11 | $1 / 4$ time |

Set the FB current.

| LEDLVSET[3:0] | LED_LV voltage setting |
| :---: | :---: |
| 0000 | LED_LV pin input |
| 0001 | 1.00 V |
| 0010 | 0.95 V |
| 0011 | 0.90 V |
| 0100 | 0.85 V |
| 0101 | 0.80 V |
| 0110 | 0.75 V |
| 0111 | 0.70 V |
| 1000 | 0.65 V |
| 1001 | 0.60 V |
| 1010 | 0.55 V |
| 1011 | 0.50 V |
| 1100 | 0.45 V |
| 1101 | 0.40 V |
| 1110 | 0.35 V |
| 1111 | 0.30 V |

Set the LED_LV voltage.
When LEDLVSET[3:0]=0000, LED_LV pin voltage will be used as reference for feedback voltage.
Other than LEDLVSET[3:0]=0000, IC internal reference voltage will be used, thus external bias setting can be removed.
If you set the LED_LV by this register, it will be the priority rather than LED_LV pin voltage.

### 1.14 PWM phase shift setting

Phase shifting for each channel is possible by setting the LEDPHASE register. In addition, by setting the LEDDIS register, unused channel also can be set. Therefore, various combinations of dimming can be performed.
1.14.1
(*1) When VCC and DVDD are supplied, STB becomes $\mathrm{L} \rightarrow \mathrm{H}, 15 \mathrm{MHz}$ oscillator for phase shift sampling will start operate.
(*2) Then, when PWM signal is supplied, counter will start at $\mathrm{L} \rightarrow \mathrm{H}$ edge as the starting point.
(*3) When PWM signal becomes $\mathrm{H} \rightarrow \mathrm{L}, \mathrm{PWM}$ 's ON width count-number $\mathrm{N}_{\text {on }}$ will be decided.
(*4) PWM's period $N_{T}$ will be decided at next PWM signal $\mathrm{L} \rightarrow \mathrm{H}$ edge when next PWM signal.
Period, duty and phase for each LED driver channel will be counted from ON width $N_{o N}$, period $N_{T}$ and LEDPHASE register setting, then PWM signal will be reflected to each channel from next PWM signal.
Phase shift is possible for frequency within 100 Hz to 20 kHz .
This function operates during DVDD is being input and the cautions are as below. Please be noted that this function does not depend on phase shift amount.
(Caution 1) Possible phase shift frequency range is 100 Hz to 25 kHz .
(Caution 2) When input the signal around PWM $=100 \%$, please don't input the pulse lower than 157 ns for Low interval. This is to correctly recognize the Low interval.

The following is the DUTY values which are not in the input range.
When PWM20kHz, above $99.68 \%, 100 \%$ and below (PWM=100\% input is possible)
When PWM500Hz, above $99.992 \%, 100 \%$ and below (PWM=100\% input is possible)
When there is no DVDD (during standalone), the PWM terminal will directly make the constant current driver goes ON/OFF, therefore above caution 1 and 2 are not applicable.


Figure 17. Timing chart for phase shift

### 1.14.2 Case when PWM is below 100 Hz , $\mathrm{PWM}=\mathrm{H}$ during overflow

When PWM signal's ON width and counter (period counting) is above $2^{18}=262144 \mathrm{clk}$ (correspond to frequency below 57 Hz ), it becomes overflow. If PWM's $L \rightarrow H$ edge is not input by this time, PWM signal's period can be decided. The operation at this condition is shown below.


Figure 18. Timing chart for $100 \%$ duty overflow
PWM input is considered as High (Duty=100\%), thus each LED driver channel will be set as Duty=100\% same timing with counter restart.

### 1.14.3 Case when PWM is below 100 Hz , PWM=L during overflow.



Figure 19. Timing chart for 0\% duty overflow
PWM input is considered as Low (Duty=0\%), thus each LED driver channel will be set as Duty=0\% same timing with counter restart.

1. Phase 1 setting ( 0 shift)

TLEDDIS $=00 \mathrm{~h}[\mathrm{All} \mathrm{ch}$ ON], LEDPHASE=00h)


Signal from PWM pin is used as PWM signal for each channel. All channels will have same phase.

2.Phase2 setting (1/2T shift)

■LEDDIS $=00 \mathrm{~h}[\mathrm{All}$ ch ON], LEDPHASE=02h


1/2T shift, mode which has 2 phases.


TEDDIS $=30 \mathrm{~h}[\mathrm{CH} 5,6$ OFF],LEDPHASE $=02 \mathrm{~h}$


Case when $\mathrm{CH} 5, \mathrm{CH} 6$ are not in use.


2LEDDIS $=3$ Ch[CH3-6 OFF], LEDPHASE=02h

3. Phase 3 setting ( $1 / 3 \mathrm{~T}$ shift)
(2LEDDIS $=00 \mathrm{~h}[\mathrm{All} \mathrm{ch} . \mathrm{ON}]$, LEDPHASE $=03 \mathrm{~h}$


- ${ }^{2}$ LEDDIS=38h[CH4-6 OFF], LEDPHASE=03h

4.Phase4 setting (1/4T shift)

TLEDDIS=00h[All ch. ON], LEDPHASE=04h


TLEDDIS=30h[LED5, 6 OFF], LEDPHASE=04h


Case when $\mathrm{CH} 5-6$ are not in use

5. Phase5 setting ( $1 / 5 \mathrm{~T}$ shift)

- ${ }^{\text {LEDDIS }}=00 \mathrm{~h}[\mathrm{All} \mathrm{ch}$. ON], LEDPHASE=05h


1/5T shift, mode which has 5 phases.


6. Phase6 setting ( $1 / 6 \mathrm{~T}$ shift)

TLEDDIS $=00 \mathrm{~h}[$ All ch. ON], LEDPHASE $=06 \mathrm{~h}$


## 2 Understanding BD9423EFV

### 2.1 Pin description

1 pin. VCC
Power supply terminal of IC. The input range is 9 to 35 V . The operation starts over VCC $=7.5 \mathrm{~V}$ (typ) and the system stops under VCC=7.2V (typ).

## 2 pin. FAIL

FAIL signal output terminal (OPEN DRAIN). NMOS is OPEN at the normal operation therefore FAIL pin is Hi-Z. It becomes FAIL=L at the abnormal detection. It is possible to select the FAIL type from latch type (FAIL_MODE=L) or one shot pulse (FAIL_MODE=H). Please refer to the detail explanation <FAIL_MODE terminal>.

## 3 pin. REG9V

REG9V is a 9 V output pin used delivering 20 mA at maximum: Using at a current higher than 20 mA may affect the reference voltage within IC.
The characteristic of VCC line regulation at REG9V is shown as figure. VCC must be used in more than 10.5 V for stable 9 V output.
Install an oscillation prevention ceramic capacitor ( $1.0 \mu \mathrm{~F}$ to $10 \mu \mathrm{~F}$ ) nearest to VREG between VREG-AGND terminals.

4 pin. N.C
Non-connect pin. Please set it the open state or deal with connecting the GND.

5 pin. N


Gate driving output pin of external NMOS of DC/DC converter with 0 to 9 V (REG9V) swing. Output resistance of source is $2.5 \Omega$ (typ), sink $3.0 \Omega$ (typ) in ON state. The oscillation frequency is set by a resistance connected to RT pin. For details, see the explanation of <RT terminal>.

## 6 pin. PGND

Power GND terminal of output terminal, N driver.
7 pin. CS
Inductor current detection resistor connecting terminal of DC/DC current mode. It transforms the current flowing through the inductor into voltage by sense resistor $\mathrm{R}_{\mathrm{CS}}$ connected to CS terminal, and this voltage is compared with that set in the error amplifier by current detection comparator to control DC/DC output voltage. RCS also performs overcurrent protection (OCP) and stops switching action when the voltage of CS terminal is 0.45 V (typ) or higher (Pulse by Pulse).
And this terminal switch the master mode and the slave mode. When the slave mode is set, please set OPEN as for CS pin. It can be set either with external pin or I2C setting by below setting.

| State | Master/Slave setting method |
| :---: | :---: |
| Without DVDD or <br> with DVDD (MSTSLVSEL=0) | CS pin |
| With DVDD <br> (MSTSLVSEL=1) | I2C (05h, Bit4) |

## 8 pin. OVP

OVP terminal is the detection terminal of overvoltage protection (OVP) and short circuit protection (SCP) for DC/DC output voltage.
OVP detection voltage can be adjusted the register OVPSET.
Depending on the setting of the FAIL_MODE terminal, FAIL and CP terminal behave differently when an abnormality is detected. For details, see the table for each protection operation is described in section 3.2 and 3.3.

## 9 pin. FAIL_MODE

Output mode of FAIL can be change by FAIL_MODE terminal.
When FAIL_MODE is in Low state, the output of FAIL terminal is the latch mode. FAIL terminal is latched if the CP charge time completed. Once IC is latched, even if the abnormal state is canceled, IC keeps stopping.
When FAIL_MODE is in Hi state, the output of FAIL terminal is one shot pulse mode. At detected abnormality, firstly FAIL is in Low state. FAIL returns to $\mathrm{Hi}-\mathrm{Z}$ if abnormality through the reset active time is released after CP charge time. In this mode, there is no latch stop for protection operation in IC. Monitoring the FAIL with the Microcomputer, decide to stop working IC. For FAIL_MODE=H when the detection sequence, see the explanation of section 3.8.4.
Changing FAIL_MODE during operating application is prohibited.

## 10 pin. AGND

GND for analog system inside IC.

## 11-16pin. LED1-LED6

LED constant current driver output terminal. Setting of LED current value is adjustable by setting the ADIM voltage and connecting a resistor to $S$ terminal. For details, see the explanation of <PIN. 25 to 30 S / PIN. 35 ADIM>.
The PWM dimming frequency of LED current driver and upper/lower limit of the duty need to be set in a manner that necessary linearity of PWM dimming characteristics can be secured referring to the following figures:

## Start/Stop time of constant current driver

Start-up time depends on the ADIM value; the response becomes quick, so that voltage is high.
In the way of reference, the current response upon application of current rise rate and pulse PWM1 s (current pulse) to describe the dependence of ADIM. It needs to be adequately verified with an actual device because the response rate may vary with application conditions.


17 pin. STB
ON/OFF setting terminal for IC, which can be used to perform a reset at shutdown.
(Caution) The voltage of STB input in the sequence of VCC $\rightarrow$ STB.
(Caution) Voltage input in STB terminal switches the state of IC (IC ON/OFF). Using the terminal between the 2 states ( 0.8 V to 2.0 V ) needs to be avoided.

## 18 pin. DVDD

Standard oscillator power supply terminal for I2C interface and phase shift usage. Please input the voltage in range of 2.7 V to 3.6 V . Please set it to GND during standalone control without I2C setting.

19, 20 pin. SDA, SCL
I2C interface terminal. Please refer to "1.12 I2C Command Interface" for input signal regulation.
Please connect to GND during standalone mode when I2C setting is not using.

## 21 pin. PWM

ON/OFF terminal of LED driver: it inputs PWM dimming signal directly to PWM terminal and change of DUTY enables dimming. High/Low level of PWM terminal is shown as follows:

| Status | PWM voltage |
| :--- | :--- |
| LED ON | PWM $=1.5 \mathrm{~V}$ to 20 V |
| LED OFF | PWM $=-0.3 \mathrm{~V}$ to 0.8 V |

There are standalone mode (without DVDD) which is the signal is directly input to PWM terminal and I2C mode (with DVDD) which is each CH set by phase difference.

Please refer to "1.14 PWM phase shift setting" for PWM terminal function of I2C mode.
This function operates during DVDD is being input and the cautions are as below. Please be noted that this function does not depend on phase shift amount.
(Caution 1) Possible phase shift frequency range is 100 Hz to 25 kHz .
(Caution 2) When input the signal around PWM $=100 \%$, please do not input the pulse lower than 157 ns for Low interval.
This is to correctly recognize the Low interval.
The following is the DUTY values which are not in the input range.
When PWM20kHz, above $99.68 \%, 100 \%$ and below (PWM=100\% input is possible).
When PWM500Hz, above $99.992 \%, 100 \%$ and below (PWM=100\% input is possible)
When there is no DVDD, the PWM terminal will directly make the constant current driver goes ON/OFF, therefore above caution 1 and 2 are not applicable.

## 22 pin. DGND

GND for DVDD power supply.

## 23 pin. SUMPWM

The pin to judge whether there is High signal is input or not for PWM terminal. When using Master/Slave mode, connect the SUMPWM to each other, when any of PWM signal became High, SUMPWM will become high. Please refer to " 3.4 operation during master slave connection" for more details.
Besides, switching Master/Slave mode can be done by register MSTSLVSEL using software control.

## 24 pin. FAIL_RST

Reset terminal of the protection circuit and FAIL terminal. Return the latch stopped protection block by setting the FAIL_RST to Hi. During Hi state, operation is masked by the latch system protection.
Moreover, it is possible to FAIL reset by register FAILSORST using software control. It can be set either with external pin or I2C setting by below setting.

| Condition | FAIL_RST setting method |
| :---: | :---: |
| Without DVDD | FAIL_RST terminal |
| With DVDD | I2C (00h, Bit1) |

When there is DVDD, please set by only I2C and set FAIL_RST to OPEN or GND.
Where there is DVDD and FAIL_RST=H, protection circuits will reset and LED will not light. The behaviors are slightly different compared to stated behaviors in above table.

## 25-30 pin. S1-S6, 35 pin. ADIM

S terminal is a connecting terminal for LED constant current setting resistor, output current ILED is in an inverse relationship to the resistance value.
ADIM terminal is a terminal for analog dimming; output current ILED is in a proportional relationship to the voltage value to be input.
ADIM terminal is assumed that it is set by dividing the resistance with a high degree of accuracy, ADIM terminal inside the IC is in open state (High Impedance). It is necessary to input the external voltage by the divide resistance from the output of REG9V or use external voltage.
The relationship among output current ILED, ADIM input voltage, and RS resistance has the following equation. (during standalone)

$$
\text { LED }=\frac{\mathrm{ADIM}[\mathrm{~V}]}{\mathrm{RS}[\Omega]} \times 0.2[\mathrm{~A}]
$$

The voltage of $S$ terminal is following equation:

$$
\mathrm{VS}=0.2 \times \mathrm{ADIM}[\mathrm{~V}]
$$



Figure 20. The relation of Sx pin and ADIM pin
(Caution) Rises LED current accelerate heat generation of IC. Adequate consideration needs to be taken to thermal design in use.
(Caution) When the ADIM voltage is changed rapidly, note that the necessary output voltage of the DC/DC converter largely changes because of LED VF change. In particularly, when the ADIM voltages become high to low, the LED terminal voltage can be higher transiently, so that may influence applications such as the LED short circuit protection. Adequate verification is necessary with an actual device as for analog dimming.

## 31 pin. CP

Terminal setting the timer latch for the abnormal detection. After the detection of LED short, LED open and SCP, it charges by the constant current $3.0 \mu \mathrm{~A}$ to the external capacitor. When the CP terminal voltage reaches 3.0 V (typ), the IC is latched and FAIL terminal operates (at FAIL_MODE=L).
The CP time can be adjusted by the register CPADJ.

## 32 pin. SS

Terminal setting the soft-start time of DC/DC converter. It performs constant current charge of $3.0 \mu \mathrm{~A}$ (typ) to the external capacitor connected with SS terminal, which enables soft-start of DC/DC converter.
Since the LED protection function (OPEN/SHORT detection) works when the SS terminal voltage reaches 4.0V (typ) or higher, it must be set to bring stability to conditions such as DC/DC output voltage and LED constant current drive operation, etc.
The SS time can be adjusted by the register SSADJ.

## 33 pin. FB

Output terminal of the error amplifier of current mode DC/DC converter.
The voltage of LED terminal which is the highest VF voltage among 6 LED strings and the voltage of LED_LV terminal become input of the error amplifier. The DC/DC output voltage is kept constant to control the duty of the output N terminal by adjusting the FB voltage.
The voltage of other LED terminals is, as a result, higher by the variation of Vf. Phase compensation setting is separately described in section 3.7.
The state in which all PWM signals are in LOW state brings high Impedance, keeping FB voltage. This action removes the time of charge to the specified voltage, which results in speed-up in DC/DC conversion.

## 34 pin. RT

RT sets frequency inside IC.
Only a resistor connected to RT determines the drive frequency inside IC, the relationship has the following equation: FCT is 200 kHz at $\mathrm{RT}=100 \mathrm{k} \Omega$. (during standalone)
The oscillation frequency can be adjusted by the register FOSC. (during I2C control)


Figure 21. The relation of RRT and oscillation frequency

## 36 pin. ADIM_P

Analog dimming usage pulse signal terminal. When analog dimming signal is input by DC signal, please pull up above 6.5 V (typ) and input DC signal at ADIM terminal. Please set the input voltage smaller than 18.0 V during normal operation.
Based on ADIM_P input level, ADIM terminal function varies as below table. Pulse-DC conversion circuit is as shown in below figure.

| ADIM_P input level | ADIM_P terminal <br> function | ADIM terminal function | Needed signal from <br> external |
| :---: | :---: | :---: | :---: |
| $-0.3 \mathrm{~V}<$ ADIM_P $<5.5 \mathrm{~V}$ | Analog dimming usage <br> pulse signal input | Analog dimming usage <br> DC signal output | Analog dimming usage <br> DUTY signal |
| $6.5 \mathrm{~V}<$ ADIM_P $<18 \mathrm{~V}$ | ADIM_P terminal <br> function mask | Analog diming usage DC <br> signal input | Analog dimming usage <br> DC signal output |



Figure 22. The relation of ADIM_P and ADIM
Based on this, it is possible to use both DUTY signal and DC signal for analog dimming usage signal input from external.
When using DUTY signal, input the DUTY signal at ADIM_P terminal around 3.0 V amplitude. In order to keep the ADIM output not to become below 0.2 V , the duty of $8 \%$ and above is needed to be input at ADIM_P.

Input frequency is expected to be until 20 kHz . When over 20khz is input, please be aware that the DC output error will become bigger over some percentage based on internal circuit delay effect. It also depends on input amplitude.
When the capacitance connected to ADIM terminal is too small, please be aware since it is possible that the ripple at ADIM terminal will become bigger and LED current different will get bigger.

When using DC signal, input the DC signal at ADIM terminal after ADIM_P terminal is pulled up by 6.5 V and above.

By using two or more of this IC, when using DUTY signal for analog dimming, the configuration will be as shown in the right figure. Channel-to-channel error can be reduced since it uses a common circuit for pulse-DC conversion circuit.
Pulse-DC conversion circuit is defined by R1 and C1 constant values and output the DC at ADIM terminal. Increasing the C1 will make the generated ripple at ADIM becomes smaller, plus the response speed also will be slower.
Besides, when ADIM terminal is pulled down by a resistor, please be aware the voltage different since the resistor R1 is as shown in above figure.


Figure 23. The example of analog dimming by duty signal with more than two IC

## 37 pin. LED_LV

LED_LV terminal sets the reference voltage error amplifier. LED_LV terminal is assumed that it is set by dividing the resistance with a high degree of accuracy, LED_LV terminal inside the IC is in open state (High Impedance). It is necessary to input voltage to divide the resistance from the output of REG9V or use external power source. Using the terminal in open state needs to be avoided.
According to output current, lowering LED_LV voltage can reduce the loss and heat generation inside IC. However, it is necessary to ensure the voltage between drain and source of FET inside IC, so LED_LV voltage has restriction on the following equation.
VLED_LV $\geqq($ LED-terminal voltage S$)+0.2 \times$ ADIM [V]
For example, at ILED $=100 \mathrm{~mA}$ setting by $A D I M=1 \mathrm{~V}$, from figure the voltage between LED and $S$ terminal is required 0.47 V , so LED_LV voltage must be at least a minimum of 0.67 V .

(Caution) Please make it linear interpolation for the middle of ILED.
(Caution) Rises in VLED_LV voltage and LED current accelerate heat generation of IC. Adequate consideration needs to be taken to thermal design in use.
(Caution) LED_LV voltage is not allowed setting below 0.3 V .
(Caution) LED current by raising LED_LV voltage can flow to MAX 400mA, use with care in the dissipation of the package.
It is possible to set the LED_LV voltage setting by I2C. It can be set either with external pin or I2C setting by below setting.

| Condition | LED_LV setting method |
| :---: | :---: |
| Without DVDD or <br> without DVDD (LEDLVSET[3:0]=0000) | LED_LV terminal |
| With DVDD |  |
| (except LEDLVSET[3:0]=0000 setting) | I2C (08h, Bit3-0) |

## 38 pin. LSP

Terminal which sets LED SHORT detection voltage: The input impedance of LSP pin is High Impedance, because it is assumed that the input of LSP terminal is set by dividing the resistance with a high degree of accuracy.
During standalone mode, it is necessary to input voltage to divide the resistance from the output of REG9V or use the external voltage. Using the terminal in open state needs to be avoided. Set LSP voltage in the range of 0.8 V to 3.0 V .
The relationship between LSP voltage and detect voltage of LED SHORT protection has the following equation.

$$
\begin{aligned}
& \text { LED }_{\text {SHORT }}=5 \times V L S P \quad[V] \\
& \text { LED }_{\text {SHORT }}: \text { LSP detection Voltage, VLSP: LSP terminal voltage }
\end{aligned}
$$

There are some restrictions for condition on short LED detection. For details, see the explanation of section 3.8.5 It can be set either with external pin or I2C setting by below setting.

| Condition | LSP setting method |
| :---: | :---: |
| Without DVDD or |  |
| with DVDD (LSPSET[3:0]=0000) | LSP terminal |
| With DVDD |  |
| (except LSPSET[3:0]=0000 setting) | I2C (04h, Bit3-0) |

39 pin. UVLO
UVLO terminal of the power of step-up DC/DC converter: at 2.5 V (typ) or higher, IC starts step-up operation and stops at 2.3V or lower (typ). UVLO can be used to perform a reset after latch stop of the protections.

The power of step-up DC/DC converter needs to be set detection level by dividing the resistance.

## 40 pin. AGND

Analog GND for IC.

## 3. Application Of BD9423EFV

### 3.1 Application circuit diagrams

Below are some examples using the basic application BD9423EFV.
3.1.1 Example of basic application (using I2C control)


The basic configuration example of peripheral circuit using I2C interface control.

### 3.1.2 Example of basic application (using standalone control)



The basic configuration example of peripheral circuit without using I2C interface control but standalone control. Please connect the I2C related terminals (DVDD, SDA and SCL) to GND.
3.1.3 Application example when there is unused LED channel during standalone (example: 5 ch and $\mathbf{6 c h}$ are unused).


This is an example of the circuit when there is unused LED channel during standalone.
Please set Sx terminal to OPEN.
Pull up LEDx terminal with 2 V to avoid abnormality.
I2C setting is done by the register.

### 3.1.4 Example of Master/Slave connection



This is the example for Master/Slave connection.
SUMPWM terminal is connected between each IC,
CS terminal of slave side is set to OPEN for the slave recognition.
When the configuration is by I2C, SDA and SCL input are needed for both IC since the slave address is same.
3.2 Protection operation during FAIL latch output (FAILMODE=L)
3.2.1 List of the protection function detection condition (typ condition)

| Protection <br> name | Detection <br> pin name | Detection condition |  | Release condition | Protection type |
| :---: | :---: | :---: | :---: | :---: | :--- |
|  | LEDx | LEDx $<0.2 \mathrm{~V}(4 \mathrm{clk})$ <br> $\mathrm{SS}>4.0 \mathrm{~V}$ | High | LEDx $>0.2 \mathrm{~V}(3 \mathrm{clk})$ | Stop the CH latch after the CP <br> charge is completed |
| LED Short | LEDx | LEDx $>5 \times \mathrm{VLSP}(4 \mathrm{clk})$ <br> SS $>4.0 \mathrm{~V}$ | High | LEDx $<5 \times \mathrm{VLSP}(3 \mathrm{clk})$ | Stop the CH latch after the CP <br> charge is completed |
| UVLO | UVLO | UVLO $<2.3 \mathrm{~V}$ | - | UVLO $>2.5 \mathrm{~V}$ | Auto-feedback (System reset) |
| OVP | OVP | OVP $>3.00 \mathrm{~V}$ | - | OVP $<2.95 \mathrm{~V}$ | Auto-feedback |
| SCP | OVP | OVP $<0.2 \mathrm{~V}$ | - | OVP $>0.2 \mathrm{~V}$ | Stop all CH latch after the CP <br> charge is completed. |
| OCP | CS | CS $>0.45 \mathrm{~V}$ | - | $\mathrm{CS}<0.25 \mathrm{~V}$ | Pulse by Pulse |

It is possible to reset with the FAIL_RST terminal to release the latch stop.

### 3.2.2 List of protection function operation

| Protection function | Protection function operation |  |  |  |
| :---: | :---: | :---: | :---: | :---: |
|  | DC/DC converter | LED driver | SS terminal | FAIL terminal |
| STB | Stop | Stop | Discharge | Hi-Z |
| LED Open | Normal operation <br> (Stop when all LED CH <br> stop) | Stop after CP charge <br> (Latch operation) | Normal operation <br> (Discharge when all <br> LED CH stop) | Low after CP charge <br> is completed <br> (Latch operation) |
| LED short | Normal operation ${ }^{\text {(Note1) }}$ | Stop after CP charge <br> (Latch operation) | Normal operation | Low after CP charge <br> is completed <br> (Latch operation) |
| UVLO | Stop | Stop | Discharge | Low |
| OVP | Stop N output | Normal operation | Normal operation | Hi-Z |
| SCP | Stop N output | Stop after CP charge <br> (Latch operation) | Discharge after latch | Low after CP charge <br> is completed <br> (Latch operation) |
| OCP | Stop the N output <br> (Pulse by Pulse) | Normal operation | Normal operation | Hi-Z |

[^0]3.3 Protection operation during FAIL one shot output (FAILMODE=H)
3.3.1 List of the protection function detection condition (typ condition)

| Protection <br> name | Detection <br> pin name | Detection condition |  | Release condition | Protection type |
| :---: | :---: | :---: | :---: | :---: | :--- |
| LED Open | LEDx | LEDx $<0.2 \mathrm{~V}(4 \mathrm{clk})$ <br> SS $>4.0 \mathrm{~V}$ | High | LEDx $>0.2 \mathrm{~V}(3 \mathrm{clk})$ | Auto-feedback after CP charge <br> and reset active time completed. |
| LED Short | LEDx | LEDx $>5 \times \mathrm{VLSP}(4 \mathrm{clk})$ <br> SS $>4.0 \mathrm{~V}$ | High | LEDx $<5^{*} \mathrm{VLSP}(3 \mathrm{clk})$ | Auto-feedback after CP charge <br> and reset active time completed. |
| UVLO | UVLO | UVLO $<2.3 \mathrm{~V}$ | - | UVLO $>2.5 \mathrm{~V}$ | Auto-feedback (System reset) |
| OVP | OVP | OVP $>3.0 \mathrm{~V}$ | - | OVP $<2.95 \mathrm{~V}$ | Auto-feedback |
| SCP | OVP | OVP $<0.2 \mathrm{~V}$ | - | OVP $>0.2 \mathrm{~V}$ | Auto-feedback after CP charge <br> and counter are completed |
| OCP | CS | $\mathrm{CS}>0.45 \mathrm{~V}$ | - | $\mathrm{CS}<0.25 \mathrm{~V}$ | Pulse by Pulse |

3.3.2 List of the protection function operation

| Protection <br> function | Protection function operation |  |  |  |
| :---: | :---: | :---: | :---: | :---: |
|  | DC/DC converter | LED driver | SS terminal | FAIL terminal |
| STB | Stop | Stop | Discharge | Hi-Z |
| LED Open | Normal operation <br> (Stop when all CH <br> stop) | Normal operation | Normal operation | Low |
| LED Short | Normal operation | Normal operation | Normal operation | Low |
| UVLO | Stop | Stop | Discharge | Low |
| OVP | Stop the N output | Normal operation | Normal operation | Low |
| SCP | Stop the N output | Normal operation | Normal operation | Low |
| OCP | Stop the $N$ output <br> (Pulse by Pulse) | Normal operation | Normal operation | Hi-Z |

### 3.4 Operation during Master/Slave connection



Figure 24. internal block for master slave function

BD9423EFV is built with a system that can drive multiple LED driver by one DCDC in Master from multiple connected BD9423EFV by using Master/Slave.
Herewith is the explanation on the operation of multiple connected IC using Master/Slave.
[MSDET] Master/Slave recognition usage comparator
Detect the CS terminal voltage, and judge by itself whether it is Master or Slave.
When using Master/Slave mode, Slave CS terminal is set to OPEN. Constant current is being supply to CS terminal by the internal IC, therefore CS terminal will be High.
A resistor is connected for DCDC switching current detection usage at Master CS terminal and swing in 0 V to 0.45 V range during operation.
The comparator will detect this voltage different and use it as Master/Slave recognition signal.
[SUMPWMDET] All PWM signals presence recognition usage comparator
At SUMPWM terminal, a switch and a pull down $100 \mathrm{k} \Omega$ resistor which will ON when PWM signal is High and if over one PWM signal became High, SUMPWM terminal will become High.
Connecting the SUMPWM terminal in between of Master/Slave will make the judgment becomes possible if over one PWM signal from all PWM signal from Master/Slave became High or not.

Error amplifier is decided based on two signals of MSDET and SUMPWM.
[1] Error amplifier output part with or without diode
If Slave mode is detected by the IC, a diode will be added at the error amplifier output and the supply at error amplifier sink side will be cut.
[2] Error amplifier output part with or without pull up resistor
IC Master mode recognition and over one Slave PWM becomes ON, a pull up resistor will be added.
[3] Error amplifier output FB output cut
In case of Master recognition, when all Master/Slave PWM signals become OFF, error amplifier output will be cut. In case of Slave recognition, when all Slave side PWM signals become OFF, error amplifier output will be cut.

The summary for above contents is shown in below table.

| Master | Slave | Master |  |  | Slave |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Error amplifier output |  |  | Error amplifier output |  |  |
|  |  | Source | Sink | Pull up | Source | Sink | Pull up |
| PWM ON | PWM ON | $\bigcirc$ | $\bigcirc$ | - | $\bigcirc$ | - | - |
| PWM ON | PWM OFF | $\bigcirc$ | $\bigcirc$ | - | - | - | - |
| PWM OFF | PWM ON | $\bigcirc$ | $\bigcirc$ | $\bigcirc$ | $\bigcirc$ | - | - |
| PWM OFF | PWM OFF | - | - | - | - | - | - |

Only Master mode usage

| Master | Master |  |  |  |
| :---: | :---: | :---: | :---: | :---: |
|  |  | Error amplifier output |  |  |
|  | Source | Sink | Pull up |  |
| PWM ON |  | $\bigcirc$ | $\bigcirc$ | - |
| PWM OFF |  | - | - | - |

In addition, Master/Slave recognition is possible to set by register MSTSLVSEL using software control. Master/Slave recognition can be set by register MSTSLVSFT.
Please refer to section 3.1.4 for circuit example.

### 3.5 Setting of the external components (typ Condition)

### 3.5.1 Setting the start-up operation and SS terminal capacitance

The explanation of start up sequence for this IC.


Figure 25. Waveform during start up


Figure 26. Circuit operation during start up

## Start up sequence

1. Basic voltage REG9V will start up at STB=H.
2. At first timing of $\mathrm{PWM}=\mathrm{H}, \mathrm{SS}$ will start to charge. At this time, the equal circuit of slow start SS voltage and FB voltage will operate and without depending on PWM logic, it will become $\mathrm{FB}=\mathrm{SS}$.
3. Since $\mathrm{FB}=\mathrm{SS}$ will achieve internal sawtooth-ish waveform lower limit, N pulse is generated and VOUT will start to increase.
4. VOUT is increased and LED current will achieve starting to flow voltage.
5. When LED current became over constant current, $\mathrm{FB}=\mathrm{SS}$ circuit will be separated and start up operation is finished.
6. After that, based on feedback operation of ISENSE terminal, it will be normal operation. In addition, even there is no flow of LED current, when SS becomes over $4.0 \mathrm{~V}, \mathrm{SS}=\mathrm{FB}$ circuit control will stop.

## SS terminal capacitance setting method (during standalone)

In addition, Master/Slave recognition is possible to set by register MSTSLVSEL using software control. Master/Slave recognition can be set by register MSTSLVSFT.
Based on previous stated sequences, when start up is finished during FB=SS, it is possible to think that the startup time Tss is from STB=On to when FB voltage achieved the feedback point.
If SS terminal capacitance is Css and the FB terminal feedback voltage after the start up is VFB, the Tss time will be as below equation.

$$
\mathrm{T}_{\mathrm{ss}}=\frac{\mathrm{C}_{\mathrm{ss}}[\mu \mathrm{~F}] \times \mathrm{VFB}[\mathrm{~V}]}{3[\mu \mathrm{~A}]} \quad[\mathrm{sec}]
$$

Reducing too much of Css, inrush current will flow to inductor during start up. However, increasing too much of Css could make the LED lights step-by-step. The constants to set the Css vary based on required charateristics and also the factors such as boost ratio, output capacitance, DCDC frequency, LED current and etc. are different, therefore please perform actual evaluation.

### 3.5.2 Setting the LED current (ADIM pin, Sx pin) (during standalone)

Firstly, decide the ADIM terminal input voltage. When using analog dimming, please be aware of ADIM terminal possible input range ( 0.2 V to 2.5 V ), and decide voltage at normal.

For this IC, Sx terminal is the standard point to control LED constant current. Sx terminal voltage should be controlled to become $1 / 5$ of ADIM voltage. When $\operatorname{ADIM}=1 \mathrm{~V}, \mathrm{Sx}=0.2 \mathrm{~V}$. Therefore, if " $R s$ " is the resistance for Sx terminal to the GND, ADIM terminal load applied voltage is " $V_{A D I M ", ~ a n d ~ t h e ~ t a r g e t ~ L E D ~ c u r r e n t ~ i s ~ " L E D ", ~ t h e ~ e q u a t i o n ~ w i l l ~ b e ~ a s ~ b e l o w . ~}^{\text {a }}$.

$$
\mathrm{R}_{\mathrm{S}}[\mathrm{ohm}]=\frac{\mathrm{V}_{\text {ADIM }}[\mathrm{V}]}{\mathrm{L}_{\text {LED }}[\mathrm{A}] \times 5}
$$

### 3.5.3 Setting the LED short detect voltage (LSP pin) (during standalone)

LED short detection voltage can be changed arbitrarily. It is possible by setting LSP pin within range ( 0.8 V to 3.0 V ). The relationship between LED short detection voltage "VLEDshort" and LSP pin voltage "VLSP" is as follows.

$$
V_{L S P}[V]=\frac{V L E D_{\text {short }}[V]}{5}
$$

Possible range setting for LSP pin setting range is 0.8 V to 3.0 V , and for VLEDshort is 4 V to 15 V .

## Equation of setting LSP detect voltage

When the detection voltage VLSP of LSP is set up by resistance division of R1 and R2 using REG9V, it becomes like the following formula.

$$
V L E D_{\text {short }}=\left(R E G 9 V \times \frac{R 2}{R 1+R 2}\right) \times 5 \quad[V]
$$



Figure 27. LSP setting circuit
(Caution) Also including the variation in IC, please also take the part variation in a set into consideration for an actual constant setup, and inquire enough to it.

### 3.5.4 Timer latch time (CP pin) (during standalone)

When various abnormalities are detected, the source current of $3.0 \mu \mathrm{~A}$ is first flowed from CP pin. BD93973EFV don't stop by latch, unless abnormal state continues and CP pin voltage reaches continuous 2 V .
With the capacity linked to CP pin, the un-responded time from detection to a latch stop. The relationship between the un-responded time Tcp and CP pin connection capacitor Ccp is as follows.

$$
C_{C P}[F]=\frac{T_{\mathrm{CP}}[S] \times 3.0 \times 10^{-6}[\mathrm{~A}]}{3.0[\mathrm{~V}]}
$$

### 3.5.5 DCDC operation frequency (RT pin) (during standalone)

The oscillation frequency of the DCDC output is decided by RT resistance.
BD9397EFV is designed to become a 200 kHz setup at the time of $100 \mathrm{k} \Omega$.
RT resistance and frequency have a relation of an inverse proportion, and become settled as the following formula.
$R_{R T}=\frac{2.0 \times 10^{10}}{f_{S W}}[\Omega]$
Here, $\quad=D C D C$ comparator external oscillator $[\mathrm{Hz}]$
$f_{s v}$
Please connect $R T$ resistance close as much as possible from RT pin and an AGND pin.

### 3.5.6 Maximum DCDC output voltage (Vout, max)

The DCDC output maximum voltage is restricted by Max Duty of $N$ output. Moreover, the voltage needed in order that Vf may modulate by LED current also with the same number of LEDs. Vf becomes high, so that there is generally much current. When you have grasped the variation factor of everything, such as variation in a DCDC input voltage range, the variation and temperature characteristics of LED load, and external parts, please carry out a margin setup.

### 3.5.7 Setting the OVP (during standalone)

Please input the voltage divided by the divider resistors at DCDC output line. In BD9423EFV, when OVP is detected, the instant stop of the $N$ pin output is carried out, and voltage rise operation is stopped. But the latch stop by CP charge is not performed. If VOUT drops by naturally discharge, it is less than the hysteresis voltage of OVP detection and the oscillation condition is fulfilled, N output will be resumed again.

## Equation of setting OVP detect

$$
V O V P=3.0 \times \frac{R 1+R 2}{R 2} \quad[V]
$$



N pin output is suspended at the time of SCP detection, it stops step-up
Figure 28. OVP setting circuit
operation, and the latch protection by CP timer.

## Equation of setting SCP detection

$$
V S C P=0.2 \times \frac{R 1+R 2}{R 2} \quad[V]
$$

### 3.5.8 FAIL logic

FAIL signal output pin. The relation logic and the output state is shown below table. Refer the section 3.2, 3.3 for the relation between this pin logic and the kind of the detection of abnormalities, FAIL_MODE.

| State | FAIL output |
| :---: | :---: |
| In Normal state, In STB=L | Hi-Z |
| When an abnormality | GND Level <br> $(300 \Omega$ typ $)$ |

### 3.5.9 Set the UVLO

UVLO terminal for step-up DCDC converter power supply. Operation starts more than 2.5 V (typ) and operation stops less than 2.3 V (typ).
Since UVLO terminal is high impedance terminal, there is no pull down at internal. Therefore, please set the voltage since the potential is not determined at open state.

## Equation of UVLO detection setting

VIN decreases, when UVLO detection voltage is VIN ${ }_{\text {DET }}$, the R1 and R2 setting is as below.

$$
R 1=R 2[k \Omega] \times \frac{V I N_{D E T}[V]-2.3[V]}{2.3[V]} \quad[k \Omega]
$$

## Equation of UVLO release setting

Based on above equation, when R1 and R2 are decided, the UVLO release


Figure 29. UVLO setting circuit voltage will be as follow equation.

$$
V I N_{C A N}=2.5[V] \times \frac{R 1[k \Omega]+R 2[k \Omega]}{R 2[k \Omega]} \quad[V]
$$

### 3.5.10 Setting of the LED_LV voltage (LED_LV pin)(during standalone)

LED_LV pin is in the OPEN (High Impedance) state.
LED_LV terminal is in open state (High Impedance). It is necessary to input voltage to divide the resistance from the output of REG9V or use external power source.

## Equation of Setting LED_LV voltage

When LED_LV voltage is set up by resistance division of R1 and R2 using REG9V, the relation is following formula.

$$
V_{L E D_{-} L V}=R E G 9 V \times \frac{R 2}{R 1+R 2}[V]
$$

(Caution) The setting constant should be adequately verified, considering IC tolerance and the components tolerance on application.

### 3.6 Selecting of DCDC parts <br> 3.6.1 Selecting inductor $L$



The value of inductor has a great influence on input ripple current. As shown in Equation (1), as the inductor becomes large and switching frequency becomes high, the ripple current of an inductor $\Delta \mathrm{IL}$ becomes low.

$$
\begin{equation*}
\Delta I L=\frac{\left(V_{O U T}-V_{I N}\right) \times V_{I N}}{L \times V_{\text {OUT }} \times f_{S W}}[A] \tag{1}
\end{equation*}
$$



When the efficiency is expressed by Equation (2), input peak current will be given by Equation (3).
$\eta=\frac{V_{\text {OUT }} \times I_{\text {OUT }}}{V_{\text {IN }} \times I_{\text {IN }}}$
$I L_{M A X}=I_{I N}+\frac{\Delta I L}{2}=\frac{V_{\text {OUT }} \times I_{\text {OUT }}}{V_{I N} \times \eta}+\frac{\Delta I L}{2}$
Here,
L : reactance value $[\mathrm{H}] \quad$ Vout: DC/DC output voltage [V]
$\mathrm{V}_{\mathrm{IN}}$ input voltage [V]
Lout: output load current (total of LED current) [A]
$\mathrm{I}_{\mathrm{in}:}$ input current $[\mathrm{A}] \quad \mathrm{F}_{\text {Sw: }}$ : oscillation frequency $[\mathrm{Hz}]$
Generally, $\Delta \mathrm{IL}$ is set at around $30-50 \%$ of output load current.

Figure 30. Coil current and boost circit
(Caution) Current exceeding the rated current value of inductor flown through the coil causes magnetic saturation, resulting in decrease in efficiency. Inductor needs to be selected to have such adequate margin that peak current does not exceed the rated current value of the inductor.
(Caution) To reduce inductor loss and improve efficiency, inductor with low resistance components (DCR, ACR) needs to be selected.

### 3.6.2 Selecting output capacitor $\mathrm{C}_{\text {оut }}$

Output capacitor needs to be selected in consideration of equivalent series resistance required to even the stable area of
 output voltage or ripple voltage. Be aware that set LED current may not be flown due to decrease in LED terminal voltage if output ripple voltage is high. Output ripple voltage $\Delta \mathrm{V}_{\text {Out }}$ is determined by Equation (4):

$$
\begin{equation*}
\Delta V_{\text {OUT }}=I L M A X \times R_{E S R}+\frac{1}{C_{\text {OUT }}} \times \frac{I_{\text {OUT }}}{\eta} \times \frac{1}{f_{S W}}[V] \tag{4}
\end{equation*}
$$

$R_{E S R}$ : equivalent series resistance of $C_{\text {OUT }}$
(Caution) Rating of capacitor needs to be selected to have adequate margin against output voltage.
(Caution) To use an electrolytic capacitor, adequate margin against allowable current is also necessary. Be aware that current larger than set value flows transitionally in case that LED is provided with PWM dimming especially.

Figure 31. Output capacitance

### 3.6.3 Selecting switching MOSFET

Though there is no problem if the absolute maximum rating is the rated current of $L$ or (withstand voltage of Cout + rectifying diode) VF or higher, one with small gate capacitance (injected charge) needs to be selected to achieve high-speed switching.
(Caution) One with over current protection setting or higher is recommended.
(Caution) Selection of one with small ON resistance results in high efficiency.

### 3.6.4 Selecting rectifying diode

A schottky barrier diode which has current ability higher than the rated current of $L$, reverse voltage larger than withstand voltage of $\mathrm{C}_{\text {out }}$, and low forward voltage VF especially needs to be selected.

### 3.6.5 Selecting MOSFET for load switch and its soft-start.

As a normal step-up DC/DC converter does not have a switch on the path from $\mathrm{V}_{\text {In }}$ to $\mathrm{V}_{\text {out, }}$, output voltage is generated even though IC is OFF. To keep output voltage at 0 V until IC works, PMOSFET for load switch needs to be inserted between $\mathrm{V}_{\mathrm{IN}}$ and the inductor. FAIL terminal needs to be used to drive the load switch. PMOSFET for the load switch of which gate-source withstand voltage and drain-source withstand voltage are both higher than $\mathrm{V}_{\text {IN }}$ needs to be selected. To provide soft-start for the load switch, a capacitor must be inserted among gates and sources.

### 3.7 How to set phase compensation

DC/DC converter application controlling current mode has each one pole (phase lag) $f_{p}$ due to CR filter composed of output capacitor and output resistance (=LED current) and ZERO (phase lead) $\mathrm{f}_{\mathrm{z}}$ by output capacitor and ESR of the capacitor. Moreover, step-up DC/DC converter has RHP ZERO $f_{\text {ZRHP }}$ as another ZERO. The operation will be unstable when this ZERO point is applied. In order to prevent unstable operation of the RHP ZERO, here the phase compensation of control loop bandwidth fc is set to $\mathrm{fc}=\mathrm{f}_{\text {ZRHP }} / 5$ (RHP ZERO frequency $\mathrm{f}_{\text {ZRHP }}$ ).
Based on response speed consideration, since the constant is not applicable, please perform sufficient actual evaluation to confirm the characteristics.


Figure 32. Output circuit and error amplifier circuit
i. Determine Pole $f_{p}$ and RHP ZERO frequency $f_{\text {ZRHP }}$ of DC/DC converter.

$$
\begin{array}{cr}
f_{p}=\frac{I_{L E D}}{2 \pi \times V_{O U T} \times C_{O U T}}[H z] & f_{\text {ZRHP }}=\frac{V_{O U T} \times(1-D)^{2}}{2 \pi \times L \times I_{L E D}}[\mathrm{~Hz}] \\
\text { Here, } \varepsilon_{L E E}=\text { Total LED current [A], } & D=\frac{V_{O U T}-V_{I N}}{V_{O U T}}
\end{array}
$$

ii. Determine Phase compensation to be inserted into error amplifier (with $f_{c}$ set at $1 / 5$ of $f_{\text {ZRHP }}$ )

$$
\begin{aligned}
& R_{F B 1}=\frac{f_{R H Z P} \times R_{C S} \times I_{L E D}}{5 \times f_{p} \times g m \times V_{O U T} \times(1-D)}[\Omega] \\
& \mathrm{C}_{\mathrm{FB} 1}=\frac{1}{2 \pi \times \mathrm{R}_{\mathrm{FB} 1 \times \mathrm{f}_{\mathrm{C}}}=\frac{5}{2 \pi \times \mathrm{R}_{\mathrm{FB} 1} \times \mathrm{f} \mathrm{ZRHP}}}\left[\begin{array}{l}
\text { Here, } \quad g m=1.036 \times 10^{-3}[\mathrm{~S}]
\end{array}\right.
\end{aligned}
$$

Above equations shows the LED lighting without the oscillation. In order to allow the response characteristic, even based on steep dimming signal, it is possible that the value might be different.
Though increase in $\mathrm{R}_{\mathrm{FB} 1}$ and decrease in $\mathrm{C}_{\mathrm{FB} 1}$ are necessary to improve transient response, it needs to be adequately verified with an actual device in consideration of variation between external parts since phase margin is decreased.

### 3.8 Timing chart

### 3.8.1 Start up and shut down sequence 1 (PWM signal input before STB input)

Please refer to "1.13 register map" for figure initial command and dimming command differentiation.

(*1)...When VCC is input stably, after minimum of $\mathrm{t} 1=1 \mathrm{~ms}$, please input the DVDD. Please firstly ON and lastly OFF the VCC.
(*2)...When DVDD is input stably, after minimum of $\mathrm{t} 2=1 \mathrm{~ms}$, please input the I 2 C command.
(*3)...Input the analog dimming signal (ADIM, ADIM_P) and PWM dimming signal. Above figure shows when ADIM_P is being input, but it will get charged by ADIM capacitance, thus ADIM voltage will gradually rise.
(*4)...Making STB $=\mathrm{L} \rightarrow \mathrm{H}$ will make REG9V to start up. During PWM signal is not being input condition, SS terminal will not get charged and booster will not start.
(*5)...SS terminal is started to charge at $\mathrm{PWM}=\mathrm{L} \rightarrow \mathrm{H}$ edge and soft start interval will start. When SS terminal is below $0.8 \mathrm{~V}, \mathrm{~N}$ terminal boost pulse will not be output. Regardless of PWM or OVP level etc., SS terminal will continuously charge.
(*6)...When SS terminal voltage Vss became 4.0V, soft start interval is finished, it should boost to set LED current flowing voltage. At this point, LED OPEN and SHORT abnormality detection will start. LED current, ILED in SS as in the description, the waveform is been simplified.
(*7)...When STB=L, instantly $\mathrm{N}=\mathrm{L}$ and $\mathrm{SS}=\mathrm{L}$ and boost operation will stop.

### 3.8.2 Normal operation sequence 2 (PWM signal input after STB)

Please refer to " 1.13 register map" for figure initial command and dimming command differentiation.

(*1)...When VCC is input stably, after minimum of $\mathrm{t} 1=1 \mathrm{~ms}$, please input the DVDD. Please firstly ON and lastly OFF the VCC.
(*2)...When DVDD is input stably, after minimum of $\mathrm{t} 2=1 \mathrm{~ms}$, please input the I2C command.
(*3)... Making STB $=\mathrm{L} \rightarrow \mathrm{H}$ will make REG9V to start up. During PWM signal is not being input condition, SS terminal will not get charged and booster will not start.
(*4)...SS terminal is started to charge at $\mathrm{PWM}=\mathrm{L} \rightarrow \mathrm{H}$ edge and soft start interval will start. When SS terminal is below $0.8 \mathrm{~V}, \mathrm{~N}$ terminal boost pulse will not be output. Regardless of PWM or OVP level etc., SS terminal will continuously $3 \mu \mathrm{~A}$ charge.
(*5)...When SS terminal voltage Vss became 4.0V, soft start interval is finished, it should boost to set LED current flowing voltage. At this point, LED OPEN and SHORT abnormality detection will start. LED current, ILED in SS as in the description, the waveform is been simplified.
(*6)...When $\mathrm{STB}=\mathrm{L}$, instantly $\mathrm{N}=\mathrm{L}$ and $\mathrm{SS}=\mathrm{L}$ and boost operation will stop.

### 3.8.3 During FAIL_MODE=L protection operation states transition sequence

CP is performed when abnormality is detected and will stop after certain constant time. The operation will remain stop even abnormality is released. Please also refer to section 3.2 condition table.
Below shows the LED short protection chart. CLK has same frequency as DCDC oscillating frequency.

(*1)...CP will not charge when PWM=H interval is 4count and below.
(*3)...When abnormality state (LEDx $>5^{*} \mathrm{VLSP}$ ) of $\mathrm{PWM}=\mathrm{H}$ interval is 4 count and above is continued, CP terminal charge will start. Once it started, the normal and abnormality is not judged based on PWM logic.
(*4)...During the CP charge, releasing the abnormality will make CP terminal discharge. (CP=Low)
(*5)...When abnormality happened again, until CP charge, the judgement takes place to determine whether the manner is same as $\left(2^{*}\right)$ when $\mathrm{PWM}=\mathrm{H}$ is 4 count and abnormal or not.
(*7)...When CP charge reached 3 V , it will be judged as abnormal, the corresponded channel will stop and FAIL=Low will be output.
(*8)...Once it stopped, even the abnormal state is been released, the corresponded channel will remain stop (latch OFF). In order to re-start the operation, either STB is set to L or FAIL_RST=H (during standalone) is input, please set register FAILSORST=1. (during I2C)

### 3.8.4 During FAIL_MODE=H protection operation sequences

If abnormality is detected, constant time of FAIL=Low will be output. FAIL output will return to FAIL=Hi-Z after "CP charge time and Reset active time" are passed from the abnormality is been released. In the meantime, we can assume that the stop signal is being input from external. Please refer to section 3.3 for condition table.
Below shows the LED short protection chart. CLK has same frequency as DCDC oscillating frequency.

### 3.8.4.1 Basic operation (abnormal state instantly released)


(*1)...The internal during 4count and below will be masked even the abnormal condition is input. At 4count and above, internal signal will be ERR=H.
(*2)...When it continues and abnormal is input, and if 3count is been input, ERR will return to $L$ then FAIL will be Low. CP charge will start. Here, after that abnormal is released instantly.
(*3)...When it reached at $\mathrm{CP}=3 \mathrm{~V}, \mathrm{CP}$ will discharge after 3count.
(*4)...When CP is discharged, reset effective timer (1024count) will operate and CP=Low and FAIL=Low is output.
(*5)...When reset active timer is finished, FAIL will return to Hi-Z.

### 3.8.4.2 Abnormal state not instantly released


(*2)...When CP charge starts, ERR will return to L and FAIL will become Low. Here, abnormal state will continue and let say short detection=H.
(*3)...ERR signal will repeatedly become H and L and CP will discharge at second negative edge. Fail will remain L. Reset active timer (1024count) will operate, in the meantime $C P=L, F A I L=L$ is being output.
(*4)...Abnormal state is been released and short detection will become L.
(*5)...Reset active timer will be finished, if it is normal operation, CP will charge again.
(*6)...When it reached at $\mathrm{CP}=3 \mathrm{~V}, \mathrm{CP}$ will be discharged after 3count.
(*7)...When reset active timer is finished, FAIL will return to Hi-Z.

### 3.8.5 LED SHORT detection

LED SHORT detection will not work as 1ch drive operation. Detection needs below conditions.

- Target CH detection is PWM=H and LED terminal voltage is over SHORT detection voltage.
- Other than that, any 1 ch is $\mathrm{PWM}=\mathrm{H}$ and LED terminal 3 V and below.
- Above two conditions continuously with DCDC oscillator frequency over 4clk.

The detection sequences are as following. (4clk mask is not shown)

3.9 I/O equivalent circuit diagram

| REG9V / N / PGND / CS | SS | FB |
| :---: | :---: | :---: |
|  |  |  |
| LED1~6 / S1~6 | CP | UVLO |
|  |  |  |
| PWM | ADIM | ADIM_P |
|  |  |  |
| OVP | FAIL | RT |
|  |  |  |
| SUMPWM / SDA / SCL | STB / FAIL_MODE / FAIL_RST | LSP / LED_LV |
|  |  |  |

## Operational Notes

1. Reverse Connection of Power Supply

Connecting the power supply in reverse polarity can damage the IC. Take precautions against reverse polarity when connecting the power supply, such as mounting an external diode between the power supply and the IC's power supply pins.

## 2. Power Supply Lines

Design the PCB layout pattern to provide low impedance supply lines. Separate the ground and supply lines of the digital and analog blocks to prevent noise in the ground and supply lines of the digital block from affecting the analog block. Furthermore, connect a capacitor to ground at all power supply pins. Consider the effect of temperature and aging on the capacitance value when using electrolytic capacitors.
3. Ground Voltage

Ensure that no pins are at a voltage below that of the ground pin at any time, even during transient condition.

## 4. Ground Wiring Pattern

When using both small-signal and large-current ground traces, the two ground traces should be routed separately but connected to a single ground at the reference point of the application board to avoid fluctuations in the small-signal ground caused by large currents. Also ensure that the ground traces of external components do not cause variations on the ground voltage. The ground lines must be as short and thick as possible to reduce line impedance.

## 5. Thermal Consideration

Should by any chance the power dissipation rating be exceeded the rise in temperature of the chip may result in deterioration of the properties of the chip. In case of exceeding this absolute maximum rating, increase the board size and copper area to prevent exceeding the Pd rating.
6. Recommended Operating Conditions

These conditions represent a range within which the expected characteristics of the IC can be approximately obtained. The electrical characteristics are guaranteed under the conditions of each parameter.

## 7. Inrush Current

When power is first supplied to the IC, it is possible that the internal logic may be unstable and inrush current may flow instantaneously due to the internal powering sequence and delays, especially if the IC has more than one power supply. Therefore, give special consideration to power coupling capacitance, power wiring, width of ground wiring, and routing of connections.
8. Operation Under Strong Electromagnetic Field

Operating the IC in the presence of a strong electromagnetic field may cause the IC to malfunction.
9. Testing on Application Boards

When testing the IC on an application board, connecting a capacitor directly to a low-impedance output pin may subject the IC to stress. Always discharge capacitors completely after each process or step. The IC's power supply should always be turned off completely before connecting or removing it from the test setup during the inspection process. To prevent damage from static discharge, ground the IC during assembly and use similar precautions during transport and storage.
10. Inter-pin Short and Mounting Errors

Ensure that the direction and position are correct when mounting the IC on the PCB. Incorrect mounting may result in damaging the IC. Avoid nearby pins being shorted to each other especially to ground, power supply and output pin. Inter-pin shorts could be due to many reasons such as metal particles, water droplets (in very humid environment) and unintentional solder bridge deposited in between pins during assembly to name a few.

## 11. Unused Input Pins

Input pins of an IC are often connected to the gate of a MOS transistor. The gate has extremely high impedance and extremely low capacitance. If left unconnected, the electric field from the outside can easily charge it. The small charge acquired in this way is enough to produce a significant effect on the conduction through the transistor and cause unexpected operation of the IC. So unless otherwise specified, unused input pins should be connected to the power supply or ground line.

## Operational Notes - continued

## 12. Regarding the Input Pin of the IC

This monolithic IC contains $\mathrm{P}+$ isolation and P substrate layers between adjacent elements in order to keep them isolated. P-N junctions are formed at the intersection of the P layers with the N layers of other elements, creating a parasitic diode or transistor. For example (refer to figure below):
When GND > Pin A and GND > Pin B, the P-N junction operates as a parasitic diode.
When GND > Pin B, the P-N junction operates as a parasitic transistor.
Parasitic diodes inevitably occur in the structure of the IC. The operation of parasitic diodes can result in mutual interference among circuits, operational faults, or physical damage. Therefore, conditions that cause these diodes to operate, such as applying a voltage lower than the GND voltage to an input pin (and thus to the $P$ substrate) should be avoided.


Figure xx. Example of monolithic IC structure

## 13. Ceramic Capacitor

When using a ceramic capacitor, determine the dielectric constant considering the change of capacitance with temperature and the decrease in nominal capacitance due to DC bias and others.
14. Area of Safe Operation (ASO)

Operate the IC such that the output voltage, output current, and power dissipation are all within the Area of Safe Operation (ASO).
15. Thermal Shutdown Circuit(TSD)

This IC has a built-in thermal shutdown circuit that prevents heat damage to the IC. Normal operation should always be within the IC's power dissipation rating. If however the rating is exceeded for a continued period, the junction temperature ( Tj ) will rise which will activate the TSD circuit that will turn OFF all output pins. When the Tj falls below the TSD threshold, the circuits are automatically restored to normal operation.
Note that the TSD circuit operates in a situation that exceeds the absolute maximum ratings and therefore, under no circumstances, should the TSD circuit be used in a set design or for any purpose other than protecting the IC from heat damage.
16. Over Current Protection Circuit (OCP)

This IC incorporates an integrated overcurrent protection circuit that is activated when the load is shorted. This protection circuit is effective in preventing damage due to sudden and unexpected incidents. However, the IC should not be used in applications characterized by continuous operation or transitioning of the protection circuit.

## Ordering Information



## Marking Diagrams

HTSSOP-B40 (TOP VIEW)


Physical Dimension, Tape and Reel Information



## Revision History

| Date | Revision |  |
| :---: | :---: | :--- |
| $9 . O c t .2015$ | 001 | New Release |
|  |  |  |

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[d] Use of our Products in places where the Products are exposed to static electricity or electromagnetic waves
[e] Use of our Products in proximity to heat-producing components, plastic cords, or other flammable items
[f] Sealing or coating our Products with resin or other coating materials
[g] Use of our Products without cleaning residue of flux (even if you use no-clean type fluxes, cleaning residue of flux is recommended); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
[h] Use of the Products in places subject to dew condensation
4. The Products are not subject to radiation-proof design.
5. Please verify and confirm characteristics of the final or mounted products in using the Products.
6. In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse. is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power; exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.
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8. Confirm that operation temperature is within the specified range described in the product specification.
9. ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

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[c] the Products are exposed to direct sunshine or condensation
[d] the Products are exposed to high Electrostatic
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[^0]:    (Note1) Short protection doesn't hang when becoming remainder 1ch. DCDC output (LED anode voltage) will decrease along with LED SHORT

